

Cite this: *Energy Environ. Sci.*,  
2025, 18, 6344

# Stretching the future: strategies and emerging trends in stretchable organic photovoltaic materials†

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Accepted 12th May 2025

DOI: 10.1039/d5ee01504a

rsc.li/ees

As the demand for wearable electronics continues to rise, the development and fabrication of intrinsically stretchable organic photovoltaics have become a significant area of research within the energy sector. To attain the necessary stretchability, researchers have invested substantial effort in improving the performance of photoactive materials. This feature article offers a concise overview and summarizes key research findings related to the design, optimization, and applications of stretchable photovoltaic materials for highly stretchable organic photovoltaics, particularly highlighting exciting progress since 2022.

## Broader context

Stretchable photovoltaics, as an emerging solar technology, offer significant advantages over traditional rigid cells, particularly in terms of their ability to meet the demand for thin, lightweight devices and convenience. The increasing global demand for wearable and flexible electronics has spurred significant interest in stretchable organic photovoltaics (s-OPVs) as a promising energy-harvesting solution. These lightweight, mechanically resilient, and solution-processable solar cells have immense potential for self-powered wearable devices, soft robotics, and bio-integrated electronics. However, achieving high efficiency while maintaining mechanical durability remains a major challenge in s-OPV development. Recent research efforts have focused on two key approaches: tailoring the chemical structure of photoactive materials to enhance intrinsic stretchability and optimizing thin-film morphology through advanced processing/casting protocols. Additionally, addressing environmental stability concerns is crucial for real-world applications. This feature article provides a comprehensive overview of recent advancements in stretchable organic photovoltaic materials, particularly highlighting progress since 2022. By examining innovative material design strategies, processing methodologies, and stability improvements, this work aims to guide future research directions toward the commercialization of s-OPVs, ultimately contributing to sustainable and flexible energy solutions.

## 1. Introduction

The global demand for reducing carbon emissions, lowering energy costs and decreasing dependence on traditional energy sources is still on the rise. Solar energy, an inexhaustible renewable energy, will continue to be a prominent spot for

research in the field of clean energy. Organic photovoltaics (OPVs) exhibit several advantages, including light weight, high transparency, large-area manufacturing, solution processing and mechanical flexibility.<sup>1–3</sup> Silicon-based cells inherently suffer from brittleness, which greatly limits their application in flexible and wearable electronics. For developing wearable applications that conform to the human body, the materials used in OPVs must withstand over 40% strain.<sup>4</sup> Therefore, there is a critical need to develop organic photovoltaic cells with mechanical flexibility and intrinsic stretchability. Due to its mechanical properties, the organic active layer makes OPVs a highly promising candidate for wearable electronic applications.<sup>5</sup>

The research on the mechanical properties of OPVs can be summarized into three stages: rigid OPVs, flexible OPVs, and stretchable OPVs (hereafter abbreviated as s-OPVs) (Fig. 1a–c).<sup>6</sup> Rigid OPVs have minimal stretchability, while flexible OPVs can tolerate some degree of vertical deformation but exhibit low stress resistance under horizontal forces, typically below 10%.

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† This work is dedicated to the 130th Anniversary of Tianjin University and the Special Collection celebrating this milestone.



Fig. 1 Three stages of the research on boosting the mechanical properties of OPVs. (a) Rigid OPVs. (b) Flexible OPVs. (c) Stretchable OPVs (s-OPVs). (d) The development of s-OPVs and several key advances.

This limitation often leads to structural damage under large strains. In contrast, s-OPVs, a recent advancement in the field of deformable devices, can undergo significant deformation from both vertical and horizontal forces without compromising the device structure or photovoltaic performance.<sup>6</sup> s-OPVs are able to withstand higher stress and accommodate a wide range of deformations, allowing them to be integrated onto arbitrary surfaces. This enhanced stretchability enables designers to incorporate solar cells into wearable devices more freely, leading to innovative and personalized products. The manufacturing of OPVs has progressed from the initial stage of rigid OPVs to the second stage of flexible OPVs. Researchers are now focusing on improving the mechanical properties of OPVs to ensure their performance meets the demands of portable electronic devices. s-OPVs offer solutions for applications that rigid or flexible OPVs cannot address, opening up new possibilities for innovation in the field. In contrast to flexible OPVs, s-OPVs require the stretchability of all components/layers of the device. The flexibility of OPVs is constrained by the mechanical properties of every layer. The substrate, serving as the foundation, typically requires good mechanical stability and flexibility to support deformation.<sup>6</sup> Electron transport layers and the anode/cathode layers are usually located at the bottom or top of the OPVs, and their compatibility with the photoactive layer and other layers must be maximized to prevent cracking or failure during stretching.<sup>7,8</sup> The photoactive layer is the most critical component of OPVs, responsible for absorbing photons and converting them into charge carriers. The stretchability of this active layer directly impacts the performance stability and efficiency of the OPVs during deformation.

For OPVs, two main types of materials are used to fabricate active layers: conjugated polymers and small molecules.

Advances in the development of polymer donors (PDs) and small molecule acceptors (SMAs) have led to a significant increase in the efficiency of laboratory-scale single junction OPVs, with efficiencies now exceeding 20%.<sup>9,10</sup> However, the state-of-the-art OPVs based on PD:SMA combinations often exhibit poor stretching performance. These materials often possess highly rigid backbones with  $\pi$ - $\pi$  conjugated structures to achieve tight molecular packing and high crystallinity, which allow electrons to delocalize effectively and help achieve the appropriate energy levels. While this rigidity is crucial for high performance, it restricts the stretchability and deformability of the active layer, limiting its ability to withstand mechanical stress in all directions. SMAs, in particular, are brittle due to their low molecular weights and their lack of long chains that are capable of bridging crystalline domains. When OPVs based on these high-performance active layers are subjected to stress, the material may crack or even break, leading to efficiency declines and, in some cases, complete failure.<sup>11–13</sup> Polymer acceptors (PAs) offer significant advantages for s-OPVs compared to SMAs due to their longer polymer chains, which provide greater flexibility and structural integrity.<sup>13,14</sup> Consequently, researchers are increasingly focusing on all-polymer solar cells (all-PSCs) that integrate PAs. Despite this, the progress of all-PSCs has been constrained by the limited availability of suitable PAs. Therefore, in addition to striving for high photovoltaic performance, it has become a pressing necessity for researchers to develop OPVs that can endure significant mechanical stresses and adapt to a multitude of deformations. This review consolidates the latest advancements in stretchable organic photovoltaic materials. Before delving into the new progress made from 2022 onward, this feature article first presents a brief overview of earlier studies to

establish a foundational understanding of the evolution of the technology. To facilitate a clearer understanding, this paper categorizes the methods of preparing stretchable photovoltaic materials into two primary approaches: (1) designing new photovoltaic materials with high stretchability, which involves tailoring the material's chemical structure for enhanced stretchability and performance, (2) adjusting the thin-film morphology of high-efficiency binary photovoltaic blends through the incorporation of a third component or other functional additives, which aims to improve the material's mechanical properties and overall stretchability. These resulted in a more robust and flexible active layer in s-OPVs. By organizing the review in this manner, the ultimate goal is to offer valuable insights that will inform future research and development efforts in the field of s-OPVs, ultimately driving innovation and facilitating practical applications in stretchable and wearable electronics.

## 2. Brief overview of the development of s-OPVs

The flexible thin-film transistor<sup>15</sup> and the all-polymer field-effect transistor<sup>16</sup> are among the earliest forms of flexible devices, which demonstrated the potential of flexible devices. Stretchable electronics is a more recent research area based on flexible electronics (Fig. 1d).

In 2011, Bao *et al.*<sup>17</sup> fabricated the first s-OPV with a bucking structure. They deposited the electrode and active layer on the elastomeric substrate which was pre-strained. Upon releasing the pre-strain, the device bulked. The buckling phenomenon provides the devices with stretchability, and the resulting OPVs exhibited elasticity under tensile strain of up to 27%. In 2012, Bauer *et al.*<sup>18</sup> prepared OPVs on polyethylene terephthalate (PET) substrates with a thickness of only 1.4  $\mu\text{m}$ . These devices were then transferred to a pre-stretched elastic support, demonstrating a power conversion efficiency (PCE) of 4.2% and a reversible tensile strain of over 300%. Similarly, methods based on the structural design of OPVs have been developed and applied to induce stretchability in rigid materials, such as spring-like structures,<sup>19</sup> textile structures<sup>20</sup> and mesh structures.<sup>21</sup> However, these methods are relatively complex and costly, compared with designing the structure of the OPVs, and the use of intrinsically stretchable materials enables large-area production at a lower cost, such as solution processing methods and printing methods.<sup>22</sup> Notably, the bulking method, which is the most prevalent among these strategies, allows for stretchability in only a predetermined direction, limiting its suitability for wearable devices. As a result, there is a pressing need to develop intrinsically s-OPVs by replacing the rigid layer with stretchable materials.

In 2012, Bao *et al.*<sup>23</sup> initially reported intrinsically s-OPVs based on the blending of two conjugated polymers (poly(3-hexylthiophene) (P3HT) and poly(2,5-bis(2-octyldodecyl)-3,6-di(thiophen-2-yl)diketopyrrolo[3,4-c]pyrrole-1,4-dione-*alt*-thieno[3,2-*b*]thiophen) (DPPT-TT)) with [6,6]-phenyl-C61-butyric acid methyl ester (PC<sub>61</sub>BM), which exhibited reversible stretchability in the resultant

OPVs. But the PCE of the OPVs based on P3HT:PC<sub>61</sub>BM and DPPT-TT:PC<sub>61</sub>BM was extremely low (<1%). Researchers have since focused on enhancing the stretchability of OPVs without compromising their photovoltaic performance. There is a trade-off between the photovoltaic and mechanical properties of active layer materials. Conjugated materials with high photovoltaic performance typically have fused rings in their molecular structure, which enhances crystallization to improve photovoltaic performance, but this rigid structure makes the active layer brittle. In addition, since the active layers often consist of two or more materials, the degree of phase separation of the different materials also affects the charge transport, and the interface between the different materials imposes a limit on the ductility of the film.

The performance of s-OPVs has been on the rise in recent years. In 2015, Kim *et al.*<sup>14</sup> reported the use of all-polymer photoactive layers for s-OPVs for the first time. Polymer acceptors are able to form entanglements with other polymers within the acceptor domains and at the interface, thereby enhancing the stretchability of films. They prepared OPVs by using poly[4,8-bis(5-(2-ethylhexyl)thiophen-2-yl)benzo[1,2-*b*:4,5-*b'*]dithiophene-*alt*-1,3-bis(thiophen-2-yl)5(2-hexyldecyl)-4*H*-thieno[3,4-*c*]pyrrole-4,6(5*H*)-dione] (PBDTTTPD) as the polymer donor and poly[[*N,N'*-bis(2-hexyldecyl)-naphthalene-1,4,5,8-bis(dicarboximide)-2,6-diyl]-*alt*-5,5'-thiophene] (P(NDI2HD-T)) as the polymer acceptor, and the result revealed that the elongation at break and the toughness of all-PSCs are over 60 times and 470 times higher, respectively, than those of fullerene PSCs. Another notable example was demonstrated by Yang *et al.*<sup>24</sup> in 2018. They synthesized a highly viscous hydrophobic polymer, poly(dimethylsiloxane-*co*-methyl phenethylsiloxane) (PDPS), and added it as an additive to the poly(6-fluoro-2,3-bis-(3-octyloxyphenyl)quinoxaline-5,8-dyl-*alt*-thiophene-2,5-diyl) (TQ-F):poly((*N,N'*-bis(2-octyldodecyl)-naphthalene-1,4,5,8-bis(dicarboximide)-2,6-diyl)-*alt*-5,5'-(2,2'-bithiophene)) (P(NDI2OD-T2, known as N2200)) matrix. The device exhibited a PCE of 5.6%, and after 100 bending cycles at a radius of 3 mm, the devices maintained 90% of their initial efficiency. Ye *et al.*<sup>25</sup> introduced a low-cost and rather common thermoplastic elastomer, polystyrene-*block*-poly(ethylene-*ran*-butylene)-*block*-polystyrene (SEBS) as the third component. The crack onset strain (COS) of the blend film gradually increased with the increase of the weight content of SEBS. The photovoltaic performance of the film was slightly improved with a 38% increase in COS at 5% SEBS content, and the photovoltaic performance of the film remained almost unchanged with a 62% increase in COS at 10% SEBS content. This study shows the potential of thermoplastic elastomers to improve OPV stretchability.

Interlayers are essential for efficient s-OPVs as they lower the energy barriers at the active layer/electrode interfaces and adjust the work functions of the electrodes. Chen *et al.*<sup>26</sup> developed a stretchable electron-extraction layer by using poly[(9,9-bis(3'-(*N,N*-dimethylamino)propyl)-2,7-fluorene)-*alt*-2,7-(9,9-dioctylfluorene)] (PFN) and nitrile butadiene rubber (NBR) blends that can withstand up to 60% strain. They prepared OPVs that maintained a PCE of 2.82% even after 10% stretching based on this electron-extraction layer. More recently, Chen *et al.*<sup>27</sup> developed a hybrid

stretchable electrode with modified PH1000 and silver nanowires (AgNWs). The incorporation of AgNWs leads to the enhancement of charge transport and the modified PH1000 improved the stretchability of the hybrid electrode. The rigid OPV based on this electrode showed a PCE over 17%, while the s-OPV exhibited over 16%.

In addition to the design of the different layers of the OPV, other findings may also contribute to the enhancement of the performance of the s-OPVs. Zhou *et al.*<sup>28</sup> fabricated stretchable all polymer OPVs with an entangled polymer additive. They observed a 4% increase of the power output after stretching to a certain strain, and this feature is of particular significance for s-OPVs to be used in wearable devices. In a more recent study, they achieved a PCE of 15% for s-OPVs, and they also found that the fracture strain values increased with film thickness.

These advancements facilitate the use of wearable electronics and other applications, thereby driving ongoing progress in traditional solar technology.

### 3. Strategies of designing stretchable organic photovoltaic materials

#### 3.1. Regulation of molecular weight

The effect of molecular weight on the mechanical properties of P3HT has been extensively studied, with significant findings reported as early as 2013.<sup>29</sup> It was observed that when P3HT is in the solid state and its molecular weight ( $M_w$ ) exceeds the critical molecular weight ( $M_c$ ), the amorphous domains and the degree of chain entanglement increase. This enhanced entanglement enables the material to undergo considerable deformation, which is crucial for stretchable applications. Recent studies have further demonstrated the impact of molecular weight on charge transport and mechanical properties of other photovoltaic polymers. It was concluded that a higher  $M_w$  leads to more molecular chain entanglement and higher quality of entanglements.<sup>30,31</sup> Entanglement between polymer chains helps to distribute the stress and dissipate the tensile energy, enhancing film ductility.

Xu *et al.*<sup>32</sup> synthesized a series of fluorine substituted benzotriazole and bithienyl-benzodithiophene-based copolymers (PBZ-2Si) based on copolymer donor J52, then the low, medium and high molecular weight siloxane-terminated side chain substituted copolymers PBZ-2Si<sub>L</sub>, PBZ-2Si<sub>M</sub> and PBZ-2Si<sub>H</sub> were synthesized. The results showed that the COS of PBZ-2Si:N2200 blends increased upon the molecular weight of PBZ-2Si (Fig. 2a). In particular, the film based on PBZ-2Si<sub>H</sub> exhibited a significantly improved COS (19.5% to 50.7%) (Fig. 2b). Moreover, after 1000 times stretching cycles at 25% strain, the OPV based on PBZ-2Si<sub>M</sub> still retained over 75% of the initial PCE, while J52 based OPV only retained 25%. Lee *et al.*<sup>33</sup> reported carboxylate-containing poly(thiophene vinylene) (PTV) with adjustable molecular weight to dissipate tensile stresses (Fig. 2c). Compared to PETTCVT-L:L8-BO, the s-OPV based on PETTCVT-H:L8-BO exhibited a PCE of 10.1%, a PCE<sub>80%</sub> of 16%, and an increase in COS from 1.3% to 7.1% was observed (Fig. 2d). In addition,

the crystallinity of PTV increases gradually with the increase of  $M_w$ , resulting in higher hole mobility, lower molecular recombination rate, and higher efficiency of the device.

#### 3.2. Molecular design

**3.2.1. Oligomerized small molecular acceptors.** The application of oligomeric acceptors is considered one of the promising strategies that combines the advantages of SMAs and PAs. Moreover, the development of dimer acceptors has been demonstrated to be a viable solution for enhancing mechanical performance while compromising the PCE minimally.

However, the currently reported oligomeric acceptor-based OPVs usually have poor stretchable properties (COS < 5–10%). The rigid structure of oligomer acceptors leads to the discontinuous crystal domains, and cracks are generated at weak interfaces between crystals and spread rapidly when the blend film is subjected to stress.

Lee *et al.*<sup>34</sup> developed a star-shaped trimeric acceptor (TYT-S) based on Y-SMA, and the s-OPVs obtained by utilizing the TYT-S achieved a PCE of 14.4%. In addition, the prepared OPVs exhibit high mechanical stability, with a PCE of 80% of the initial value when subjected to 31% strain. These star-shaped molecular structures prevent the formation of rigid crystalline domains while increasing the extent of amorphous regions, which improves the stretchability of the resulting films.

The synthesis of dimer acceptors can be achieved through three distinct methodologies: end-to-end connection, face-to-face connection, and back-to-back connection. Among these, the end-to-end connection, due to its linear structure akin to polymerized small molecule acceptors (PSMAs), is frequently employed. The spacers currently in use are conjugated rigid fused rings,<sup>35</sup> and flexible spacers.<sup>36</sup> The introduction of these spacers has been observed to increase the conformational uncertainty and reduce the persistence length of polymers, suppressing the crystallinity of the active layer material and preventing the crystallization domains from aggregation.

Based on 2,2'-((2Z,2'Z)-((3,9-bis(2-butyloctyl)-12,13-bis(2-octyldodecyl)-12,13-dihydro-[1,2,5]thiadiazolo[3,4-]thieno[2'',3'':4',5']-thieno[2',3':4,5]pyrrolo[3,2-]thieno[2',3':4,5] thieno[3,2-*b*]indole-2,10-diyl)bis(methanylyli-dene))bis(5,6-dichloro-3-oxo-2,3-dihydro-1*H*-indene-2,1-diyl)-dene)) dimalononitrile (MY-BO), Yin *et al.*<sup>37</sup> synthesized the conjugated dimer acceptor DY-TVCl and the non-conjugated dimer acceptor DY-3T. The COS of the MY-BO based film was 4.98%, while the COS of PM6:DY-TVCl and PM6:DY-3T reached 8.26% and 10.31%, respectively. Ding *et al.*<sup>38</sup> utilized thiophene-alkane-thiophene (TAT) as a conjugate-break linker, and synthesized dimer acceptors through halogen atom substitution and modulation of the linking site (Fig. 3a). In contrast to the end-to-end conformation, the above dimeric acceptors were developed in center-to-center conformation in this paper.<sup>39</sup> The COS of the PM6:Y6 film is 8.50%, while the PM6:FDY-m-TAT film has a COS of 18.23% (Fig. 3b). The larger molecular size of FDY-m-TAT is favorable for the formation of a more robust blend film. In addition, the FDY-m-TAT molecules are not only entangled with themselves, but also form an entangled structure with PM6, whereas Y6 is only entangled between the molecules, which



Fig. 2 (a) The chemical structure of PBZ-2Si<sub>L</sub>, PBZ-2Si<sub>M</sub> and PBZ-2Si<sub>H</sub>. (b) The stress–strain curves of the J52/PBZ-2Si<sub>L</sub>/PBZ-2Si<sub>M</sub>/PBZ-2Si<sub>H</sub>:N2200 blend films under the pseudo free-standing tensile test. (c) The chemical structure of PETTCVT. (d) The stress–strain curves of the PETTCVT-L/PETTCVT-M/PETTCVT-H:L8-BO. (a) and (b) Reproduced with permission from ref. 32. Copyright 2022, Elsevier. (c) and (d) Reproduced with permission from ref. 33. Copyright 2023, Wiley-VC.

makes the former favorable for the improvement of tensile properties of the blend film. Lee *et al.*<sup>40</sup> developed a novel series of dimeric SMAs, designated as DYBT-CX (where X = 0, 4, and 8) (Fig. 3a), by incorporating various flexible units. Among the OPVs fabricated with these materials, the PBQX-TF:DYBT-C4 blend exhibited the highest COS of 32%, while the PBQX-TF:MYT-based devices achieved only 10% (Fig. 3c). Furthermore, the is-OPVs utilizing PBQX-TF:DYBT-C4 demonstrated excellent mechanical stability, retaining 80% of the initial PCE under a 36% strain. Although the DYBT-C8 has the longer FS units than DYBT-C4, the blends based on DYBT-C8 showed domain size crossing multiple length scales (63 and 18 nm), while the PBQX-TF:DYBT-C4 showed a small and uniform values of 21 nm. This leads to the different mechanical performances. Liu *et al.*<sup>41</sup> designed a series of dimer acceptors 2BOHD-TC<sub>X</sub>T (X = 4 or 6); these dimer acceptors with flexible segments can form more entanglements with donors, and PM6:2BOHD-TC4T exhibited a COS value of 9.69%, which is almost twice as much as PM6:BOHD (COS = 4.81%). According to the study by Zhang *et al.*,<sup>42</sup> they introduced a flexible alkyl linker between the precursor CH8-T, synthesizing two dimeric acceptors CH8-6 and CH8-7 (Fig. 3a). The COS of the PM6:CH8-6, PM6:CH8-7, and PM6:CH8-T blend films was 40.2%, 41.9%, and 28.3%, respectively (Fig. 3d). Song *et al.*<sup>43</sup> designed and

synthesized the dimer acceptor (DOY-TVTT) (Fig. 3a) and doped DOY-TVTT into the D18:N3 system. The addition of 15% DOY-TVTT to the D18:N3 binary blended films resulted in a nearly 50% increase in COS (from  $7.5 \pm 0.6\%$  to over 11%) and a 23.2% and 25.8% decrease in modulus of elasticity and stiffness (Fig. 3e). The flexible OSCs based on the oligomers exhibited excellent photovoltaic performance, and reached the PCE of 18.06%. The ternary flexible devices retained 97% of the initial PCE after 3000 bending cycles, while the binary device maintained only 88.4%. Qi *et al.*<sup>44</sup> introduced an alkyl linker into the Y6-derivative T9TBO, synthesizing a new dimer acceptor dT9TBO, and the mechanical properties of the ternary OPV based on PM6:Y6:dT9TBO were improved due to the incorporation of flexible alkyl linker. You *et al.*<sup>45</sup> developed a series of back-to-back connected dimer acceptors (2Qx-TT, 2Qx-C3, and 2Qx-C6) (Fig. 3a). When incorporated into the PM6:BTP-eC9 system, these dimers have been shown to optimize the film-forming kinetics and improve the PCE of the devices. The OPVs based on PM6:BTP-eC9 exhibited a PCE of 17.63%, and the addition of the dimer acceptors improved the PCE to over 18%. Furthermore, the incorporation of dimers with flexible linkage resulted in an enhanced robustness of the active layer, and a significant increase in the COS value of PM6:BTP-eC9:2Qx-C3 to 15.0% (Fig. 3f). Ye *et al.*<sup>46</sup> developed and incorporated a series of ductile



**Fig. 3** (a) The chemical structure of the oligomerized acceptors mentioned in the context. (b) The stress–strain curves of the PM6:Y6 and PM6:FDY-m-TAT blend films. (c) The stress–strain curves of the PBQx-TF:MYT, PBQx-TF:DYBT-CX (X = 0, 4, and 8) blend films. (d) Histograms of COS of PM6:CH8-6, PM6:CH8-7, and PM6:CH8-T blend films. (e) Comparison of COS, elastic modulus, and stiffness between D18:N3-based binary and ternary films. (f) The stress–strain curves of PM6:BTP-eC9 and PM6:BTP-eC9:2Qx-C3 blend films. (g) The stress–strain curves of D18:N3:DOY-C2, D18:N3:DOY-C4, and D18:N3:TOY-C4 blend films. (b) Reproduced with permission from ref. 38. Copyright 2024, Wiley-VCH. (c) Reproduced with permission from ref. 40. Copyright 2024, Elsevier. (d) Reproduced with permission from ref. 42. Copyright 2024, Royal Society of Chemistry. (e) Reproduced with permission from ref. 43. Copyright 2023, Wiley-VCH. (f) Reproduced with permission from ref. 45. Copyright 2024, Wiley-VCH. (g) Reproduced with permission from ref. 46. Copyright 2023, Wiley-VCH.



Fig. 4 (a) The chemical structure of the conventional PM6 and PM6-*b*-PDMS. (b) The chemical structure of the conventional DYBT and DYPDMS. (c) The stress–strain curves of the PM6:DYBT and PM6-*b*-PDMS:DYBT blend films. (d) The stress–strain curves of the PM6-*b*-PDMS:acceptors (DYBT, DYBT:PDMS, and DYBT:DYPDMS). (e) Strain-induced power output changed in the resulting devices: normalized power output vs. engineering strain curves. Reproduced with permission from ref. 47. Copyright 2025, Royal Society of Chemistry.

oligomeric acceptors (DOY-C2, DOY-C4, and TOY-C4) (Fig. 3a) into the D18:N3 system. A substantial enhancement in all COS values of the ternary films was observed, with a notable increase from 7.8% to approximately 12% (Fig. 3g). The D18:N3:DOY-C4 based flexible OPVs exhibited a PCE of 17.80%, while that for the binary flexible OPVs was 16.85%.

Lee *et al.*<sup>47</sup> linked two Y-based SMA units with polydimethylsiloxane (PDMS), resulting in the synthesis of an elastomer-incorporated dimer acceptor, referred to as DYPDMS (Fig. 4b). Additionally, they integrated PDMS into PM6 (Fig. 4a), thereby developing a block copolymer PM6-*b*-PDMS. By combining these two materials, the resulting is-OPV with a PDMS-incorporated active layer achieved a power conversion efficiency (PCE) of 12.7%. More importantly, this is-OPVs system demonstrated a notable enhancement in power output under strain (Fig. 4e). This study confirms the feasibility of incorporating elastomers into SMA to enhance the mechanical performance of the blended film.

**3.2.2. Polymerized small-molecule acceptor.** PAs have emerged as a promising approach for the development of high s-OPVs in comparison to SMAs. However, blend films incorporating PSMA

remain too fragile to meet the requirements for s-OPVs due to their low COS. In response to this challenge, Lee *et al.*<sup>48</sup> synthesized Y5T8T-Br and subsequently polymerized it with another conjugated monomer, benzodithiophene (BDT). This led to the development of PSMA<sub>s</sub> incorporating sequence-regular flexible spacer (SR-FS) units. The inclusion of these flexible spacer units effectively mitigates the rigidities of the polymer backbone. Notably, the PBDB-T:PYFS-Reg (Fig. 5a) blend, which consists of alternating copolymerized regular sequences of BDT and FS units (each comprising 50%), demonstrated exceptional performance in all-polymer solar cells (PSCs), achieving a PCE of 16.1% and a COS of 22.4% (Fig. 5b), significantly outperforming other PBDB-T:PSMA-based all-PSCs. The s-OPV based on PBDB-T:PYFS-Reg exhibited a PCE of 10.6% and PCE<sub>80%</sub> of 36.7%.

In another study, Lee *et al.*<sup>49</sup> synthesized a new series of PSMA<sub>s</sub>, designated as PYSiO-*X* (where *X* = 0, 5, 10, 20, and 30) (Fig. 5a), by incorporating SiO-functionalized flexible spacer (SiO-FS) units into the backbone of the PSMA. The results revealed that the inclusion of 10 mol% SiO-FS helps to enhance the performance of the all-polymer solar cells (PSCs), achieving



**Fig. 5** (a) The chemical structure of the polymerized small-molecule acceptors mentioned in the context. (b) The stress–strain curves of the PBDB-T:PYBDT, PBDB-T:PYT8T, PBDB-T:PYFS-Ran, and PBDB-T:PYFS-Reg blend films. (c) The stress–strain curves of the PBDB-T:PYSiO-X ( $X = 0, 5, 10, 20,$  and  $30$ ) blend films. (d) The stress–strain curves of the PM6:PY-IT and PM6:PYF1-B blend films. (e) The stress–strain curves of the PM6:Y6, PM6:DY-FBrL and PM6:PDY-FL blend films. (b) Reproduced with permission from ref. 48. Copyright 2022, Royal Society of Chemistry. (c) Reproduced with permission from ref. 49. Copyright 2022, Royal Society of Chemistry. (d) Reproduced with permission from ref. 50. Copyright 2024, Elsevier. (e) Reproduced with permission from ref. 51. Copyright 2025, Wiley-VCH.

a COS of 15.2% (Fig. 5c). In contrast, the all-PSCs fabricated with the PSMA lacking SiO-FS exhibited a substantially lower COS of 9.6%. Hu *et al.*<sup>50</sup> synthesized four distinct acceptors—PY-IT, PY-IF1, PYF1-A, and PYF1-B, by integrating both rigid-bridge and flexible-bridge strategies (Fig. 5a). The introduction of flexible-bridges, which partially replace the thiophene rigid-bridges, significantly enhances the performance of the resulting material. Notably, the PM6:PYF1-B blend

demonstrates a COS of 16.08%, a substantial improvement compared to the 8.67% achieved by the PM6:PY-IT blend (Fig. 5d). Ding *et al.*<sup>51</sup> synthesized a dimer acceptor DY-FBrL first, with the reaction sites of DY-FBrL, they designed a new polymerized acceptor PDY-FL (Fig. 5a). With the donor PM6, the active layer based on the DY-FBrL showed a COS of 18.54%, and the blend film based on PDY-FL reached a COS of 23.45% (Fig. 5e).

**3.2.3. Backbone engineering.** Rigid molecular structures have been shown to facilitate high crystallinity and improve efficiency. However, when the backbone structure is excessively rigid, the self-aggregation effect of the molecules becomes stronger, resulting in a brittle and weak blend film, and thereby compromising the mechanical properties. It is essential to balance the photovoltaic and mechanical properties through the design of polymer backbones. Luo *et al.*<sup>52</sup> introduced flexible segments of bis(2-thienyl)ethene (TVT) and (1,8-octanediy)l)bsthiophene (TOT) into the conjugated polymers PTzBI-Si and P(NDI2OD-T2). The resulting PTzBI-Si:P(NDI2OD-T2) film exhibited high brittleness, with a COS value of  $\sim 2.1\%$ . Further optimization of the film morphology was conducted using the solvent additive dibenzyl ether, resulting in a COS value exceeding 20% for the PO-5:NV-10 film. Liu *et al.*<sup>53</sup>

introduced flexible non-conjugated units into the polymer acceptor PY-IT and synthesized terpolymer acceptors PYTX-A and PYTX-B (X = Cl or H). The COS values of PM6:PYTX-A and PM6:PYTX-B were found to be higher than those of PM6:PY-IT, with values of 17.20% and 18.67%, respectively. By introducing non-conjugated units into PM6, the COS value PM6:PYTX-B achieved 22.74%.

Lee *et al.*<sup>54</sup> synthesized a  $P_D$  of poly[didecyl-5-(4,8-bis(5-(2-ethylhexyl)-4-fluorothiophen-2-yl)-6-methylbenzo [1,2-*b*:4,5-*b'*]-dithiophen-2-yl)-5''-methyl-[2,2':5',2''-terthiophene]-3,3''-dicarboxylate] (PBET-TF) (Fig. 6a). Then they paired PBET-TF with MYBO, and the blends showed a significantly improved COS of 31%. (Fig. 6b). After 30% strain, the PBET-TF:MYBO blend films did not show any crack, while the PBDB-TF:MYBO blend films showed a sharp crack after 3% strain. It is important to



**Fig. 6** (a) The chemical structure of the polymer acceptors mentioned in the context including the incorporation of conjugation-break spacers, and block copolymerization. (b) The stress-strain curves of the PBDB-TF:MYBO and PBET-TF:MYBO blend films. (c) The stress-strain curves of the PM6:Y6-BO, PM6-B10:Y6-BO, and PM6-B20:Y6-BO films. (d) The stress-strain curves of the  $P_D$ : L8-BO blend films ( $P_D$ : D18, D18<sub>0.8-r</sub>-PEHDT<sub>0.2</sub>, D18<sub>0.8-s</sub>-PEHDT<sub>0.2</sub>, PEHDT, and D18<sub>0.8</sub>-PEHDT<sub>0.2</sub>). (e) The stress-strain curves of the F<sub>s</sub>-MCD:BTP-eC9 blend films. (b) Reproduced with permission from ref. 54. Copyright 2024, Elsevier. (c) Reproduced with permission from ref. 55. Copyright 2023, Royal Society of Chemistry. (d) Reproduced with permission from ref. 56. Copyright 2023, Elsevier. (e) Reproduced with permission from ref. 57. Copyright 2024, Wiley-VCH.

note that PBET-TF:MYBO-based *s*-OPVs demonstrated a power output enhancement of over 5% at 40% strain. In contrast, PBDB-TF:MYBO-based *is*-OPVs maintained only 13% of the initial power output at 20% strain.

To reduce the stiffness of the polymer backbone and enhance the film's ductility, incorporating bulky electroactive units into the polymer chains is also a feasible approach. Kim *et al.*<sup>55</sup> synthesized a series of terpolymers (PM6-BX,  $X = 10-30$ ) (Fig. 6a) based on PM6 by adding 7,8-bis(5-hexylthiophen-2-yl)-11*H*-benzo[4,5]imidazo[2,1-*a*]isoindol-11-one (BID). The mechanical properties of the PM6-B10:L8-BO blend films were much greater than those of PM6:L8-BO ( $\text{COS}_{\text{avg}} = 11.4\%$  vis  $\text{COS}_{\text{avg}} = 2.0\%$ ; toughness =  $4.1 \text{ MJ m}^{-3}$  vis toughness =  $0.3 \text{ MJ m}^{-3}$ ) (Fig. 6c). The stretchable device based on the PM6-B10:L8-BO blend film with TPU substrate cracked only when subjected to 30% stress, while the stretchable device based on the PM6:L8-BO blend film cracked at only 10% stress.

The incorporation of multi-component copolymerized donors (MCDs) into the active layer has been demonstrated

to enhance the stretchability of blends. This is achieved by reducing the excessive rigidity of the polymer donor backbone and the formation of large crystalline domains, combining the benefits of the mechanical and electrical properties of the two blocks that are phase separated at the nanoscale. Lee *et al.*<sup>56</sup> synthesized the block copolymer D18<sub>0.8</sub>-*s*-PEHDT<sub>0.2</sub> with rigid D18 and soft PEHDT (Fig. 6a), a polymer donor composed of alternating soft and hard segments by sequential block copolymerization. This allowed the OPV to balance stretchability with PCE. The stretchable device based on D18<sub>0.8</sub>-*s*-PEHDT<sub>0.2</sub> achieved an efficiency of 14.3% and preserved 80% of the initial PCE at 31% strain. The COS value of D18<sub>0.8</sub>-*s*-PEHDT<sub>0.2</sub>:L8-BO reached to 17.2%, while the D18:L8-BO showed only 1.5% (Fig. 6d). In another study, Lin *et al.*<sup>57</sup> developed a series of flexible linker-sequential block MCDs, they incorporated flexible functional groups into the conjugated polymer backbone, by incorporating 1,10-bis(5-(trimethylstannyl)thiophen-2-yl)decane (BTD) as the flexible linker, and the pure film of PM6-Cl<sub>0.8</sub>-*b*-D18-Cl<sub>0.2</sub>-BTD (Fig. 6a) achieved a COS



**Fig. 7** (a) The chemical structure of PhAmX ( $X = 3, 5, 10$ ). (b) The stress–strain curves of the blend films of PM6:Y7, PhAm3:Y7, PhAm5:Y7 and PhAm10:Y7. (c) Images of blend films during the tensile test. (d) The chemical structure of N2200-ThyDap. (e) The stress–strain curves of the blend films of PM6:Y6-BO, PM6:Y6-BO:N2200 and PM6:Y6-BO:N2200-ThyDap (wt% value of  $P_A$  indicates the weight of  $P_A$  compared to ( $P_A + \text{SMA}$ ) weight). (f) Images of blend films during the tensile test. (g) The chemical structure of PM7-ThyX ( $X = 5, 10, 20$ ). (h) The stress–strain curves of the blend films of PM7:L8-BO, PM7-Thy5:L8BO, and PM7-Thy10:L8-BO. (i) Images of blend films during the tensile test. (b) and (c) Reproduced with permission from ref. 59. Copyright 2022, Wiley-VCH. (e) and (f) Reproduced with permission from ref. 60. Copyright 2023, American Chemical Society. (h) and (i) Reproduced with permission from ref. 62. Copyright 2023, American Chemical Society.

of 49.88%. This Fs-MCDs:BTP-eC9 based blend exhibited a COS value of 31.29% (Fig. 6e). Furthermore, the flexible OPVs reached a PCE of 16.63%. Lee *et al.*<sup>58</sup> developed a series of  $M_w$ -controlled  $P_D$ - $b$ -elastomer block copolymers (D18x- $b$ -PDMS, x = L, M, and H). The D18:L8-BO:PDMS ternary blend films physically mixed with PDMS had significantly lower mechanical robustness (toughness =  $0.1 \text{ MJ m}^{-3}$ ) than the D18:L8-BO blend. In contrast, the active layer based on D18x- $b$ -PDMS exhibits excellent mechanical robustness with a toughness of  $1.8$ – $2.6 \text{ MJ m}^{-3}$ , which is 4–5 times higher than the reference D18:L8-BO active layer ( $0.5 \text{ MJ m}^{-3}$ ). The s-OPVs based on D18:L8-BO and D18<sub>H</sub>- $b$ -PDMS:L8-BO exhibited PCE values of 12.4% and 11.9%, respectively. However, the strain at PCE<sub>80</sub> was 8% for the D18:L8-BO s-OPVs and 16% for the D18<sub>H</sub>- $b$ -PDMS:L8-BO s-OPVs.

Hydrogen bonding (H-bonding) is stronger than other interaction forces, and this strong intermolecular interaction with a bonding energy of  $10$ – $40 \text{ kJ mol}^{-1}$  improves the stretchability of polymer films.<sup>59–61</sup> A novel polymer donor, PhAmX (where X = 3, 5 and 10) (Fig. 7a) was synthesized based on a flexible spacer with the ability to form hydrogen bonds by Lee and his coworkers.<sup>59</sup> As the value of X increased, the COS value of the PhAmX:Y7 hybrid film increased from 10.4% (PhAm3:Y7) to 22.6% (PhAm10:Y7) (Fig. 7b). The toughness increased from  $0.30 \text{ MJ m}^{-3}$  for PM6:Y7 to  $8.42 \text{ MJ m}^{-3}$  for PhAm10:Y7. Furthermore, the s-OPVs based on the PhAm5:Y7 system reached a PCE of 12.7%, with a strain of 32% at 80% PCE, which represents a significantly higher level of stretchability than the brittle PM6:Y7 based system (PCE<sub>80%</sub> = 15%). The improved ductility of the active layer was attributed to the reversible hydrogen bonding between the PhAmX molecular chains. In order to illustrate the effect of hydrogen bonding on the mechanical properties of the films, a comparison was made between the properties of the blend films obtained from aliphatic flexible spacer-containing units and those from flexible spacer units with the ability to form hydrogen bonds. It was found that the stretchability of the PhAm10-based blend film (COS = 23%) was significantly improved compared to the blend film obtained by incorporating normal flexible spacers (PM6-C10, COS = 9%). Wan *et al.*<sup>60</sup> synthesized a conjugated polymer acceptor, N2200-ThyDap (Fig. 7d), which has greatly enhanced intermolecular interactions through the formation of hydrogen bonds between thymine (Thy) and diaminopyrazine (Dap) on N2200-ThyDap. In addition, the results revealed that the hydrogen bonding in N2200-ThyDap helps to connect the isolated domains between the SMAs, allowing the amorphous behavior to be enhanced and contributing to the improvement of the ternary OPV stretchability. The blend film based on PM6:Y6:N2200-ThyDap achieves a COS value of 4.8%, while the blend film based on PM6:Y6:N2200 has a COS value of only 2.1% (Fig. 7e). Wan *et al.*<sup>62</sup> synthesized a series of derivative polymers of PM7 (PM7-Thy5, PM7-Thy10 and PM7-Thy20) (Fig. 7g) by introducing difluoro quinoxaline with a thymine (Thy) end group in the side chain. The stretchability of the blend films was enhanced due to the ability of the introduced Q-Thy units to form hydrogen bonding between the chains. The COS of the PM7:L8-BO based film is only 2.6%, whereas the

COS of the PM7-Thy10:L8-BO based film is greater than 13% (Fig. 7h). And the PM7-Thy10-based s-OPVs showed higher PCE than the PM7-based s-OPV, with a strain at PCE<sub>80%</sub> of 43.1%. In the study by Wang *et al.*,<sup>63</sup> PM6 and PY-IT were selected as the basis polymer, and amide units with alkyl segments and hydrogen bonds were introduced into the basis polymer. The introduction of the amide units resulted in a decrease in the crystallinity of the polymer due to its flexible segments and led to an improvement in the intermolecular force because of the strong hydrogen bonding energy, promoting the stretchability of the blend films.

**3.2.4. Side chain engineering.** Side chain engineering such as grafting new functional groups, and changing the type of branching and side chain length are effective strategies to change the polymer solubility, molecular stacking and film morphology.<sup>64,65</sup> Li *et al.*<sup>66</sup> introduced long branched alkyl side chains into PM6 to obtain the polymer PM6-HD (Fig. 8a). With high molecular weight, these side chains weakened the interactions between PM6-HD side chains and the  $\pi$ - $\pi$  direction, thus improving the ductility of the blend film, and the resulting s-OPV demonstrates a record PCE<sub>80%</sub> strain of 50.3% (Fig. 8a).

On the other hand, rational design of side chains can improve the mechanical properties of conjugated polymers. In 2014, Lipomi *et al.*<sup>70</sup> demonstrated that appropriate alkyl chain lengths are beneficial in improving both photovoltaic and mechanical performance. They discovered that for the same number of carbon atoms, branched chains have a greater positive impact than side chains. And compared with normal terminal alkane side chains, terminal siloxane conjugated polymers have larger free volume and longer interchain distance of the polymer backbone, which may produce lower film modulus and better film ductility. He *et al.*<sup>67</sup> synthesized a polymer acceptor PY-SiO with siloxane-terminated side chains and compared its properties with those of PY-EH, which has ethylhexyl-terminated side chains (Fig. 8b). The results demonstrated that the incorporation of siloxane side chains facilitated the aggregation of PY-SiO molecules and led to the promotion of phase separation between the donor and acceptor, thereby enhancing the efficiency of the resulting OPV (10.85% to 12.04%). The siloxane side chains resulted in larger molecular chain spacing, larger chain free volume, and easier chain rotation and reconfiguration among the backbones of the polymerized acceptors, which led to an increase in the COS of the film to 18.32% (Fig. 8b), in comparison to 11.15% for the PY-EH-based film. In a study by Wang *et al.*,<sup>32</sup> the siloxane-functionalized polymer PBZ-2Si<sub>M</sub>:N2200 blend film exhibited a COS value of 38.4% and an E-modulus value of 0.30 GPa, which were significantly higher than those of the J52:N2200 system (COS = 19.5%,  $E = 0.42 \text{ GPa}$ ).

In a more recent study by Wang *et al.*,<sup>68</sup> they reported an organosilane-functionalized SMA BTP-Si4 (Fig. 8c) and blended BTP-Si4 with PNTB6-Cl. It is established that SMAs usually suppress ductility, but the addition of BTP-Si4 has been shown to enhance this property. The dichroic ratio (DR) of the PNTB6-Cl:BTP-Si4 blend films exhibited a consistent increase up to a maximum strain of 100% (Fig. 8c), indicative of remarkable



**Fig. 8** (a) The chemical structure of PM6-HD and the stress–strain curves of the blend films with different contents of PM6-HD. (b) The chemical structure of PY-EH and PY-SiO and the stress–strain curves of the blend films based on PY-EH and PY-SiO. (c) The chemical structure of BTP-Si4 and the stress–strain curves of the blend films of PNTB6-Cl:Y6 and PNTB6-Cl:BTP-Si4. (d) The chemical structure of BTP-C3, BTP-EH and BTP-HD and the stress–strain curves of the blend films of D18:BTP-C3, D18:BTP-EH and D18:BTP-HD. (a) Reproduced with permission from ref. 66. Copyright 2024, Wiley-VCH. (b) Reproduced with permission from ref. 67. Copyright 2024, American Chemical Society. (c) Reproduced with permission from ref. 68. Copyright 2025, Science. (d) Reproduced with permission from ref. 69. Copyright 2025, Royal Society of Chemistry.

strain tolerance. The s-OPVs on the basis of PNTB6-Cl:BTP-Si4 exhibited a PCE of 14.6%. In addition, only a mild decrease in PCE (approximately 25%) was experienced after 1000 cycles under 30% strain. They also synthesized a series of BTP-Si4-like SMA (BTP-Si4, BTP-Si6, and BTP-Si8), which were different in the length preceding the branching point. The design of the branch of BTP-Si4-like SMAs promoted the miscibility with the donor polymer and increased the free volume in blend films, thus led to an improvement of PCE and mechanical performance. Zhang *et al.*<sup>69</sup> synthesized three SMAs: BTP-C3, BTP-EH and BTP-HD (Fig. 8d), and these molecules share an identical dithienothiophen[3,2-*b*]-pyrrolobenzothiadiazole core but they vary in terms of branching position on the pyrrole rings and length of the branching alkyl chains. The blend films based on BTP-C3, BTP-EH and BTP-HD showed a COS of 19.6%, 25.8% and 32.5%, respectively (Fig. 8d). The BTP-EH exhibited the best miscibility with D18, and the s-OPVs based on BTP-EH achieved a PCE of 15.6%. After 1000 cycles, the BTP-EH and BTP-HD based s-OPVs exhibited 30% and 25% decrease in PCE while the BTP-C3 based s-OPVs decreased to 70% of the initial value after only 100 cycles.

### 3.3. Incorporation of a third component

Unlike the complicated chemical synthesis, the ternary blends can be prepared by adding another donor or acceptor component to the binary blends, and the introduction of the third component can play a facilitating role in various aspects such as light absorption and charge transport, which can improve the stretchability of the film more simply, and this method has been recognized as one of the most effective

methods to improve the properties of the blend films, as shown in Fig. 9.

**3.3.1. Secondary donor/acceptor.** Blending two structurally different polymer donors with a small molecule acceptor is an effective method to improve the properties of s-OPVs. The blending of two different donors can regulate the glass transition temperature of the materials and improve the molecular stacking, which leads to the enhancement of the ordering and the improvement of the mechanical properties of the blending film. In addition, the introduction of two polymer donors can optimize the compatibility of the interface of D/A, which further improves the mechanical properties of the blending system.

Ma *et al.*<sup>71</sup> improved the ductility of the blend film by introducing PBDB-TF, a polymer donor with high  $M_w$  into the PBQx-TF:PY-IT system. The high  $M_w$  PBDB-TF effectively dissipates stress, improves the stretchability of blend films, and even after 2000 continuous bending cycles, the device can still maintain 91% of its initial values. Li *et al.*<sup>72</sup> introduced a conjugated polymer PTQ10 as the second donor to the PM6:N3 blend. When 20 wt% of the third component PTQ10 was added, the PCE and COS were the best among the tested OPVs. The introduction of PTQ10 led to the  $\pi$ - $\pi$  stacking and molecular arrangement being more ordered, which results in the improvement of the stretchability of film. The modulus of elasticity decreased monotonically with the increasing PTQ10 content. In another example, Li *et al.*<sup>66</sup> synthesized a PM6 derivative with a long alkyl chain, PM6-HD, which was incorporated into binary blending systems PM6:BTP-eC9 and PM6:N2200. The addition of PM6-HD resulted in a notable enhancement in the PCE<sub>80%</sub> strain, with increases observed in both the



Fig. 9 The chemical structure of the donors and acceptors mentioned in the secondary donor/acceptor strategy.

PM6:BTP-eC9 (from 11% to 21%) and PM6:N2200 (from 31% to 50%) systems. *s*-OPVs based on PM6:PM6-HD:BTP-eC9 blends demonstrated remarkable resilience, retaining 52% of the initial PCE after 500 cycles. In comparison, OPVs based on PM6:PM6-HD:N2200 blends exhibited superior durability, with more than 80% retention of PCE after 1000 cycles of stretching. Li *et al.*<sup>3</sup> introduced PM6-OD, a PM6-like donor polymer containing long branched alkyl chains, into PM6:PY-IT blends to build intrinsically stretchable active layers of all-polymer OPVs. The incorporation of the third component PM6-HD has been shown to result in a consistent and incremental rise in COS. When the donor in the active layer is neat PM6-OD, the COS exhibited an increase of more than fourfold in comparison with the reference value. The underlying causes of these observations are likely attributable to the formation of chain entanglements in extended chains of high molecular weight, in addition to the modification of side chains.

Liu *et al.*<sup>73</sup> constructed a ternary system by adding a polymerized fullerene material, PPCBMB, to the PM6:PYIT system. The results demonstrated that an increase in the concentration of PPCBMC in the blends led to a rise in both the COS ( $9.6 \pm 1.2\%$  to  $13.1 \pm 1.3\%$ ) and strain-at-break (6.6% to 7.4%), thus enhancing the ductility of the film. The smaller domain size in the optimal ternary blend contributes to improved ductility by minimizing the number of sites where cracks can initiate. Kim *et al.*<sup>74</sup> developed novel electroactive compatibilizers P1

and P2 as the third component of the active layer of PBQx-TF:PYIT for all-polymer solar cells, whereas P2-based OPVs exhibited a PCE of 13.7%, with a PCE<sub>80%</sub> enhancement of 35%, whereas the efficiency of the stretchable device for the binary system of PBQx-TF:PYIT without the use of compatibilizers is only 12.1%, with a PCE<sub>80%</sub> was 27%. In addition, the P2-based PBQx-TF:P2:PYIT ternary hybrid films exhibited enhanced mechanical durability with  $G_c$  and COS values of  $2.6 \text{ J m}^{-2}$  and 20.4%, respectively, compared to the binary hybrid films ( $G_c = 1.1 \text{ J m}^{-2}$  and COS = 16.5%). It was found that the addition of these compatibilizers strengthened the donor-acceptor interface and the ternary blends were more cohesive, which prevented the film from being damaged by external stresses.

Wang *et al.*<sup>75</sup> introduced N2200 into the PM6:Y6 active layer blends. N2200 act as tie molecules to improve the interfacial interaction between PM6 and Y6, leading to the enhancement of stretchability. The ductility of the film increases with N200 content, the  $E$  of films show a decrease, with  $E$  values of 0.84, 0.79, and 0.60 GPa for 10%, 20%, and 30% N2200 incorporation, respectively. Zhou *et al.*<sup>28</sup> employed a strategy of entangled polymer additives to optimize the morphology of the film. By incorporating conjugated polymer PNDI with a molecular weight exceeding its critical entanglement molecular weight ( $M_c$ ) as a polymer additive, it was found that P180k (PNDI with a  $M_w$  of  $180 \text{ g mol}^{-1}$ ) exhibited the best miscibility with the host

photovoltaic material. Its entangled structure effectively hindered the propagation of cracks in the film, resulting in COS exceeding 50% for the ternary blend. When the s-OPV based on PM6:PY-IT:P180k was subjected to 30% strain and stretched 600 times repeatedly, its efficiency remained above 70% of the initial PCE. Xian *et al.*<sup>76</sup> incorporated a thiophene-dicarboxylate spacer tethered molecule TDY- $\alpha$  as a function aid into the PM6:eC9 system. With the addition of the thick bulk-heterojunction strategy, the stretchability of the blend film has been greatly improved. Furthermore, they discovered that the COS of TDY- $\alpha$  toughened blend films increased with the thickness of films. The COS for the 70 nm thick blend film is the smallest (6.1%), while the 100 nm thick film has a COS of 8.6%. In contrast, the film with 300 nm thickness shows a much higher COS of 15.6%. When the active layer thickness exceeded 300 nm, thick film s-OPVs maintained more than 80% of their initial efficiency after 1000 stretch–release cycles at 15% strain. In contrast, thin-film devices show significant damage after repeated mechanical stress.

The fabrication of ternary OPVs by adding polymer acceptors with larger molecular weight is just as good an approach. Song *et al.*<sup>77</sup> introduced the polymer PY-IT into the PM6:BTP-eC9 system to form a chain-entangled structure to produce a high-performance, intrinsically heat-resistant s-OPV. In this work, the ternary system of PM6:BTP-eC9:PY-IT OPV exhibited a PCE of 15.30%. In addition, the similar backbone structure of PY-IT and BTP-eC9 makes PY-IT more compatible with the donor material leading to the presence of a large number of connecting molecules and the formation of entangled chain networks, and the COS of the ternary blend films with 10% and 20% PY-IT were increased by 17.14% and 27.14%, respectively. The efficiency of the best ternary device was retained by 88% after 200 cycles at 8% tensile strain, which was 23.8% higher than that of the binary device, and it indicated that the entangled structure could dissipate the stresses well and avoid the device from degrading or damaging under stretching. Peng *et al.*<sup>78</sup> added a highly ductile conjugated polymer acceptor P(NDI2OD-T2) into the system of PM6:N3. They found that adding 10 wt% of P(NDI2OD-T2) can enhance the photovoltaic performance by increasing the  $\pi$ - $\pi$  stacking order and surface accumulation, optimizing domain size, and increasing the planarity of acceptor domains. The long P(NDI2OD-T2) chains formed linker molecules and entangled structures, which effectively connected the isolated regions in the active layer and provided a channel for the transport of carriers, and this entangled structure also facilitates the mechanical properties of the blend film and enhances the stretchability of the OPVs.

The second donor is typically a polymer with high molecular weight, which enhances the mechanical properties of blend films through intermolecular interactions and chain entanglements. The complementary absorption spectra of different donors broaden the spectral response range, thereby elevating the PCE. However, precise tuning of donor energy levels *via* copolymerization or side-chain modification is essential to minimize inter-donor disparities. Furthermore, solvent compatibility must be evaluated to prevent phase separation during

blending. In high-efficiency active layer systems, acceptors are often rigid molecules that compromise film stretchability. Additionally, energy level mismatches between acceptors may induce charge recombination at interfaces, further limiting device stability. To reconcile photovoltaic performance with mechanical robustness, the development of high molecular weight acceptors and non-fullerene acceptors must be considered. These strategies remain constrained by challenges such as complex synthesis ways and limited scalability. When evaluating the two strategies for optimizing s-OPVs, while both offer benefits, the second donor strategy exhibits a more pronounced synergy in simultaneously improving mechanical properties and PCEs. This is attributed to its capacity to enhance both light-harvesting and mechanical resilience through polymer design.

**3.3.2. Insulating elastomer.** The introduction of elastomers allows films to dissipate tensile stresses during stretching through the deformation of the elastomer, imparting elasticity to the conjugated films and allowing them to recover from deformation after stretching. The improvement in mechanical properties may be attributed to the partial miscibility of the elastomer, and it provides an efficient means of transferring the load between the elastomer and the semiconductor area.<sup>79–81</sup>

Elastomers currently employed in s-OPVs typically exhibit low modulus and high tensile strength as their defining characteristics. These materials, for instance SEBS, achieve such mechanical performance through their structures, where soft segments composed of flexible chains mediate energy dissipation *via* molecular chain sliding under strain. Meanwhile, rigid segments (*e.g.*, crystalline domains or aromatic units) act as crosslinking points, preventing the fracture of films by stabilizing the polymer network. This synergistic interplay enables precise tuning of the blend film's mechanical properties. Additionally, elastomers containing hydrogen-bonding groups (such as PVA) endow the blended film with self-healing capabilities. Such dynamic bonds reorganize under mechanical deformation, suppressing crack propagation and enhancing device durability under strain. Beyond mechanical considerations, economic feasibility can also be prioritized in photovoltaic applications. The selection of elastomers should balance their cost-effectiveness and availability with performance requirements.

To optimize elastomer efficacy, the optimal concentration within the active layer must be explored. The percolation threshold—the critical composition ratio at which a minority polymer forms a network within the matrix represents a pivotal parameter in blend design. Below this threshold, isolated elastomer domains fail to establish effective stress-dissipating pathways; above it, excessive elastomer loading may disrupt the conjugated polymer domain organization, compromising charge transport.<sup>82</sup> By adjusting the elastomer-to-conjugated polymer ratio, an interconnected network can be achieved. The conjugated polymers form ordered  $\pi$ -stacked domains for efficient charge transport, while the elastomer phase establishes a network that redistributes strain energy. This dual functionality ensures that the active layer retains high photovoltaic performance even under extreme mechanical deformation.



Fig. 10 (a) The chemical structure of the elastomers used as the third component in the active layer. (b) The stress–strain curves of dilute-absorber blend films with different weight fractions of elastomer. (c) Normalized PCE as a function of the strain for devices with and without 15% EVA. (d) Stress–strain curves of the blend films with different contents of PU. (e) The stress–strain curves of PM6:Y6 and PM6:Y6 with 15 wt% of K-BA20 and K-BA50. (b) Reproduced with permission from ref. 83. Copyright 2023, Wiley-VCH. (c) Reproduced with permission from ref. 88. Copyright 2024, Wiley-VCH. (d) Reproduced with permission from ref. 89. Copyright 2024, Wiley-VCH. (e) Reproduced with permission from ref. 90. Copyright 2023, Elsevier.

Li *et al.*<sup>83</sup> demonstrated the potential of elastomeric diluents for a wide range of applications in s-OPVs by using a commercially available polymer elastomer as a diluent for PM6:PYFT-*o* (Fig. 10a). At a fraction of 41% elastomer in the active layer, the fracture strain of the blend film was >50% and PCE >10%, and at up to 90% elastomer mass fraction, the fracture strain of the blend film was >1000% and elastic recovery (ER) >90%

(Fig. 10b). Lee *et al.*<sup>84</sup> developed an active layer based on the co-continuous structure of the conjugated polymer D18 and the thermoplastic elastomer SEBS. It was found that when the ratio of D18 to SEBS is 40:60 w/w, D18 and SEBS can form an optimal co-continuous structure, which provides a channel for the dissipation of stress. The s-OPV based on D18<sub>0.4</sub>:SEBS<sub>0.6</sub>:L8-BO retained 86% of the initial PCE at 50% strain and 90% PCE

retention after 200 cycles of cyclic stretching at 15% strain. Tang *et al.*<sup>85</sup> successfully induced the formation of a high-density fibrous network with low crystallinity in the bottom D18 layer. Additionally, they effectively inhibited the generation of a large phase separation between Y6 and SEBS in the top layer by employing a sequential deposition technique, wherein the bottom D18 layer and the top Y6:SEBS layer were deposited with the addition of the additive *p*-xylene in the primary solvent. Furthermore, the solid additive 1,3-dibromo-5-chlorobenzene was employed to facilitate the formation of more ordered crystalline domains of Y6 within the SEBS matrix. This resulted in the effective dissipation of stress on the active layer, and the s-OPV based on this active layer exhibited up to 26.38% COS with a 16.54% PCE. Zhang *et al.*<sup>86</sup> incorporated SEBS into small-molecule donor B1 and acceptor BTP-eC9-4F to fabricate s-OPVs. The crystalline quality of the blend film can be enhanced by SEBS through its ability to prolong the duration of both nucleation and rearrangement during the process. This leads to a reduction in recombination losses and an improvement in PCE. Furthermore, during the stretching process, the SEBS segments within the films absorb and release mechanical stresses, enhancing tensile ability. The blend film with 10% SEBS achieved a COS of 5.28%. After 10% stretching, the stretchable devices based on B1:BTP-eC9-4F containing 0%, 1% and 10% SEBS demonstrated a maintenance of 24.18%, 34.06%, and 62.36% of their initial PCEs, respectively. These findings outlined a straightforward strategy for achieving s-OPVs using all small molecules. Zheng *et al.*<sup>87</sup> fabricated intrinsically s-OPVs with top-illuminated structures by adding 5–10% styrene–ethylene–propylene–styrene triblock copolymer (SEPS) to the PM6:L8-BO:BTP-eC9 active layer system, achieving an efficiency of 15.71% and a PCE retention rate of more than 80% after 200 stretching cycles at 10% strain. Yang *et al.*<sup>88</sup> added ethylene-vinyl acetate (EVA) (Fig. 10a) into the PTzBI-oF:PYIT all-polymer blends. The addition of EVA proves that the formation of dual-network helps dissipate applied strains in the ternary system. Intrinsically stretchable devices based on active layers of PTzBI-oF:PYIT and PTzBI-oF:PYIT:15% EVA were fabricated to verify the effectiveness of EVA. The initial PCE of the PTzBI-oF:PYIT:15% EVA device was 10.73%, and its PCE retained 8.74% at 30% strain. In contrast, the EVA-free devices exhibited a similar PCE of 10.81%, and the PCE quickly dropped to 7.33% when only 20% strain was applied (Fig. 10c). Li *et al.*<sup>89</sup> enhanced the mechanical properties of PM6:PBQx-TF:PY-IT blends by adding polyurethane (PU) (Fig. 10a). The COS value increased with the content of PU (Fig. 10d). The incorporation of thermoplastic elastomer led to the PCE retention of 85.75% and 96.06% in 25 cm<sup>2</sup> flexible and super-flexible devices with 1% PU addition. In the study by Kang *et al.*,<sup>90</sup> isophorone diisocyanate (IPDI) was used as the linking unit in the design and synthesis of polyurethane insulation K-BA20 (or 50), which contains PDMS and 2D aryl block 9,9-diphenyl-9H-fluorene (DPF). The incorporation of 15 wt% K-BA20 into the PM6:Y6 blend film resulted in a 3.2-fold enhancement in the elongation at break, from 5.81% to 18.46% (Fig. 10e). And the presence of intermolecular hydrogen bonds has been demonstrated to result in the formation of strong interlayer adhesion, thereby ensuring the stability of the photovoltaic devices under stress conditions.

The elevated COS of these insulating polymers is attributable to their chemical structure. However, the disparity in surface energy between conjugated and insulating polymers inevitably results in the segregation of disparate domains, thereby influencing the performance of OPVs. To improve the miscibility between conjugated polymer and insulating polymer, Zhang *et al.*<sup>91</sup> introduced varied carboxyl groups into the side chains of SBS, synthesizing SBS-COOH (Fig. 10a) with differing surface energy. The resultant films (PM6:SBS-COOH) exhibited significantly enhanced mechanical stretchability, attributable to both enhanced miscibility and hydrogen bonding interactions between PM6 and SBS-COOH. Following the incorporation of SBS-COOH, the PM6: 20% SBS-COOH blend demonstrated a COS of 21.48%, which is significantly higher than that of the pure PM6 film (8.32%) and the PM6:20% SBS blend (5.93%).

**3.3.3. Other additives.** Solvent additives have different solubilities for donor or acceptor materials, which can alter the phase separation process during film formation. Therefore, solvent additives play an important role in modulating the microstructure of active layer films to improve OPV performance. Ding *et al.*<sup>92</sup> added solvent additive 1-chloronaphthalene (CN) (Fig. 11a) to the ternary system based on PM6:Y6 and elastomer SEBS to regulate the microstructure of the ternary system and realize the improvement of photovoltaic and mechanical properties. Ultimately, it was found that with the addition of 0.3% CN, the organic solar cell PCE of the PM6:Y6:SEBS ternary system was 15.03% and the COS value was 15.70%, while the COS of the ternary hybrid film without CN was 11.62%. The domains of SEBS were found to be smaller, which may be due to the PM6 aggregation or the diffusion of PM6 and Y6 from the SEBS-rich phase in the presence of residual CN. This ultimately led to an increase in the interfacial area between the elastomer and the photoreactive material, which is supposed to be the reason for the increase in the COS of the blend film.

Adding crosslinking agents to limit the rearrangement of polymers or small molecules in the blend film is one of the ways to improve the stretchability of OPVs. Using a photocrosslinkable small molecule 2,6-bis(4-azidobenzylidene) cyclohexanone (BAC) (Fig. 11b) as the crosslinking agent, Wang *et al.*<sup>93</sup> controlled the crosslink density by controlling the concentration of crosslinker added and the crosslinking time, resulting in an increase in the elongation of the PM6:Y6 blend film from 4.5% to 18%, and they found that with a cross-linking time of 90 seconds, the stretchability of the films reached 20%. The decrease in elongation at 120 seconds may be due to the long crosslinking time and the high crosslinking density that stiffens the polymer network structure and greatly reduces the ability of the polymer chains to move under external strains. The s-OPV prepared on this basis retained 64% of the initial PCE after 1000 tensile cycles and the strain at 80% of PCE was 20%. Tseng *et al.*<sup>94</sup> synthesized a D–A block copolymer (PM6-*b*-PYIT) (Fig. 11c). This copolymer worked as a compatibilizer in the PM6:L8-BO based active layer, and the high molecular structure similarity between the PM6-*b*-PYIT and the host



Table 1 Summary of the characteristics of the s-OPVs involved in the article

Active layer	Initial PCE (%)	Strain at PCE80% (%)	COS (%)	Applied strain (%)	PCE retention (Cycles)	Ref.
J52:N2200	4.30	<20	19.5	25	25% (1000)	32
PBZ-2Si <sub>M</sub> :N2200	6.00	50	38.4	25	75% (1000)	32
PETTCVT-L:L8-BO	6.27	7	1.3	—	—	33
PETTCVT-M:L8-BO	8.04	11	3.7	—	—	33
PETTCVT-H:L8-BO	10.1	16	7.1	—	—	33
D18:MYT	12.19	8	1.3	10	3% (120)	34
D18:TYT-L	13.10	16	6.4	10	37% (120)	34
D18:TYT-S	14.37	31	21.6	10	79% (120)	34
PM6:Y6	12.80	~10	8.5	—	—	38
PM6:FDY-m-TAT	14.29	~20	18.2	—	—	38
PBQx-TF:MYT	12.14	15	10.3	20	9% (120)	40
PBQx-TF:DYBT-C0	13.19	21	17.3	20	27% (120)	40
PBQx-TF:DYBT-C4	14.25	35	31.8	20	70% (120)	40
PBQx-TF:DYBT-C8	12.55	30	28.0	20	75% (120)	40
PM6- <i>b</i> -PDMS:DYBT;DYPDMS	12.74	41	31.9	10	80% (100)	47
PBDB-T:PYDBT	8.54	18.0	11.7	—	—	48
PBDB-T:PYFS-Ran	8.17	32.1	18.1	—	—	48
PBDB-T:PYFS-Reg	10.64	36.7	22.4	—	—	48
PM6:Y6	12.79	11	8.17	—	—	51
PM6:DY-FBrL	14.31	23	18.54	—	—	51
PM6:PDY-FL	11.61	31	23.45	—	—	51
PBDB-TF:MYBO	12.89	11.7	2	10	<25% (100)	54
PBET-TF:MYBO	12.93	50.7	31	10	>75% (150)	54
D18:L8-BO	12.77	7	1.5	10	8% (100)	56
D18 <sub>0.8-r</sub> -PEHDT <sub>0.2</sub> :L8-BO	10.97	18	10.4	10	54% (100)	56
D18 <sub>0.8-s</sub> -PEHDT <sub>0.2</sub> :L8-BO	14.31	31	17.2	10	75%	56
D18 <sub>0.8</sub> -PEHDT <sub>0.2</sub> :L8-BO	11.71	12	5.6	10	31% (100)	56
D18:L8-BO	12.4	8	1.9	—	—	58
D18 <sub>H</sub> - <i>b</i> -PDMS:L8-BO	11.9	16	6.6	—	—	58
PM6:Y7	11.05	15	1.8	15	41% (120)	59
PhAm5:Y7	12.73	31.6	13.8	15	86% (120)	59
PM7:L8-BO	11.28	16.5	2.6	—	—	62
PM7-Thy10:LB-BO	13.69	43.1	13.7	—	—	62
PM6:BTP-eC9	8.20	11	4.4	30	34% (100)	66
PM6:PM6-HD:BTP-eC9	7.12	21	12.1	30	52% (500)	66
PM6:N2200	3.21	31	—	30	53% (1000)	66
PM6:PM6-HD:N2200	2.28	50	—	30	80% (1000)	66
PBDB-T:PY-EH	8.2	<10	11.15	—	—	67
PBDB-T:PY-SiO	9.8	~15	18.32	—	—	67
PNTB6-Cl:BTP-Si4	14.1	~80	—	30	75% (1000)	68
D18:BTP-C3	14.9	~20	19.6	10	70% (100)	69
D18:BTP-EH	15.6	~30	25.8	10	70% (1000)	69
D18:BTP-HD	13.7	~30	32.5	10	75% (1000)	69
PBQx-TF:PYIT	12.14	27	19.45	15	72% (400)	74
PBQx-TF:P2:PYI	13.71	35	20.42	15	90% (400)	74
PM6:N2200:Y6	13.3	20	—	15	67% (1000)	75
PM6:PY-IT:P180k	12.35	51.2	15.0	50	>70%	28
PM6:eC9:TDY- $\alpha$	10.16	—	17.7	15	83% (1000)	76
PM6:BTP-eC9:PY-IT	15.30	—	8.2	5	88% (200)	77
PM6:PYFT- <i>o</i> :SEBS	10.16	—	—	30	~80% (500)	83
D18 <sub>0.4</sub> :SEBS <sub>0.6</sub> /L8-BO	8.51	~50	126	15	90% (200)	84
D18:Y6:SEBS	16.54	—	26.38	—	—	85
PM6:L8-BO:BTP-eC9:SEPS	15.71	—	14.0	10	71.2% (200)	87
PTzBI- <i>o</i> F:PYIT:EVA	10.73	30	17.23	—	—	88
PM6:Y6:BAC	13.4	20	—	20	64% (1000)	93

In order to achieve the greatest possible elasticity from a given material without compromising charge transport, it is essential to ensure that key material properties are carefully balanced. It is now established that the molecular weight, the regioregularity of the molecules, the side chain and the rigidity of the backbone all exert a significant influence on the ductility of the material and the electronic properties of the films. (2) Addition of a third component and additive: the incorporation of a third component and additives, such as an insulating polymer rubber with ductility, a secondary donor or acceptor, and an

electroactive compatibility agent, can serve to enhance the mechanical properties of the blend film. Further developments will be placed on self-healing, easily crosslinkable and stimuli-responsive/smart organic photovoltaic materials with high intrinsic stretchability.

Despite the rapid development of s-OPVs, their efficiency remains inferior to that of their rigid and flexible counterparts within the same system. There is a clear need for further research and innovation in the field of stretchable photoactive materials to fully realize the advancement of wearable devices.

Table 2 Summary of the characteristics of the OPVs based on stretchable active layers mentioned in the article

Active layer	Initial PCE (%)	COS (%)	Bending radius (mm)	PCE retention (Cycles)	Ref.
PM6:CH8-6	16.2	40.2	5	>96% (1200)	42
PM6:CH8-7	15.8	41.9	5	>96% (1200)	42
PM6:CH8-T	15.9	28.3	5	~92% (600)	42
D18:N3	17.35	7.5	2	88.4% (3000)	43
D18:N3:DOY-TVT	18.06	11.2	2	97% (3000)	43
PM6:BTP-eC9	14.60	5.4	3	77% (1000)	45
PM6:BTP-eC9:2Qx-C3	16.09	15.0	3	84.9% (1000)	45
D18:N3	17.06	7.8	2	89% (2000)	46
D18:N3:DOY-C2	17.23	11.5	2	96% (2000)	46
D18:N3:DOY-C4	17.91	11.7	2	98% (2000)	46
D18:N3:TOY-C4	16.41	12.1	2	98% (2000)	46
PM6:MY-BO	13.52	4.98	5	57% (1500)	37
PM6:DY-TVCl	15.23	8.26	5	79% (1500)	37
PM6:DY-3T	14.34	10.31	5	90% (1500)	37
PM6:BOHD	11.06	4.81	3	~65% (800)	41
PM6:2BOHD-T	12.45	6.23	3	~65% (800)	41
PM6:2BOHD-TC <sub>4</sub> T	12.77	9.69	3	84.2% (800)	41
PM6:2BOHD-TC <sub>6</sub> T	10.94	10.51	3	88.1% (800)	41
PM6:Y6	13.83	—	7.35	~80% (1500)	44
PM6:Y6:dT9TBO	14.86	—	7.35	~95% (1500)	44
PM6:PY-IT	12.29	8.67	—	89% (1000)	50
PM6:PYF1-B	13.42	16.08	—	92% (1000)	50
PM6:PY-IT	12.86	9.67	4	82.46% (2000)	53
PM6-A:PYTCl-A	13.81	20.10	4	91.34% (2000)	53
PM6-Cl <sub>0.8</sub> -b-D18-Cl <sub>0.2</sub> -BTD:BTP-eC9	16.63	31.29	8	95% (2000)	57
PBQx-TF:PBDB-TF:PY-IT	16.5	6.1	8	91% (2000)	71
PM6:PBQx-TF:PY-IT:PU	19.40	—	—	96.98% (2000)	89
PM6:Y6:K-BA20	11.70	—	6	37% (600)	90
PM6:Y6:K-BA50	11.31	—	6	53% (600)	90
B1:BTP-eC9-4F:SEBS	8.57	5.28	—	61.7% (100)	86
PM6:L8-BO:SBS-COOH	15.43	—	1	88.9% (40 000)	91

(1) A comprehensive understanding of the alterations in film morphology of the active layer during stretching and releasing is essential to elucidate the underlying mechanism behind the changes in the mechanical properties of the active material and to provide insights for the design of new stretchable photoactive materials. *In situ* stretching analysis of thin films is a crucial method that can help us to observe nanoscale morphological transition points during film stretching. For example, *in situ* grazing-incidence X-ray scattering<sup>96</sup> and *in situ* wide/small angle X-ray scattering<sup>78</sup> characterizations can achieve this purpose. Notably, a very recent study<sup>97</sup> developed a temperature-controlled, rotatable *in situ* stretching sample stage device capable of performing *in situ* GIWAXS tests under variable temperature stretching conditions, which provides a new method for characterizing the molecular packing in the films. Moving forward, the development of novel *in situ* experimental set-ups and AI-driven data analysis methods should be continued in order to further deepen the understanding of the behavior of polymer films under tensile conditions, thus contributing to the improvement of film properties.

(2) Beyond ensuring the stability of mechanical properties, maintaining the operational stability of s-OPVs is equally crucial for their long-term reliability and performance.<sup>98,99</sup> External factors such as oxygen and humidity pose significant threats to device efficiency and lifespan by accelerating material degradation.<sup>100</sup> Consequently, effective environmental protection is a key priority in s-OPV development. To mitigate these risks, the development of effective encapsulation materials is

essential. These materials must form an effective barrier to prevent moisture and oxygen infiltration, safeguarding the delicate active layers within the device. Additionally, achieving high optical transparency in these encapsulation materials is critical to ensure minimal interference with light absorption and energy conversion. Balancing these protective properties with optical performance is vital for enhancing the durability and efficiency of s-OPVs in real-world applications, particularly in wearable electronics and other flexible technologies.

(3) Mechanical properties of polymer blend films are often characterized by their COS values. Beyond this point, cracks begin to appear in the film, resulting in a degradation of the film properties. However, COS does not adequately represent the alterations in the film during elastic deformation. Furthermore, it has been demonstrated that, upon the surpassing of the yield point, the material will undergo irreversible deformation, which will have a significant effect on the film properties. Consequently, in addition to augmenting the value of COS, it is imperative to investigate methodologies for extending the range of elastic deformation and quantifying the fracture/adhesion energy of the film. Characterisation of the mechanical properties of free-standing films is also crucial.

(4) In addition to the design of the active layer, optimizing the fabrication process of s-OPVs is crucial for streamlining the preparation process while enhancing the performance.<sup>101–103</sup> This is a highly significant step towards advancing the commercialization of s-OPV. Solution-based continuous deposition has proven effective for laboratory-scale OPV production;

however, it is more complex for large-scale fabrication. This approach leverages molecular self-assembly to construct active and transport layers. While self-assembling deposition offers notable advantages, such as improved interface quality and enhanced cell performance, it requires precise molecular design to ensure effective self-organization. When successful, this method not only simplifies the fabrication process but also achieves an improvement in the performance of the cell, making it a promising avenue for scalable s-OPV production.

## Author contributions

J. Z. conducted the literature review, performed data analysis, prepared figures, and wrote the initial draft of the manuscript. D. H., H. Y., and V. K. contributed to scientific discussions and assisted in manuscript editing. L. Y. supervised the overall research project and provided critical revisions to the manuscript. All authors reviewed and approved the final version of the manuscript.

## Data availability

No primary research results, software or code have been included and no new data were generated or analysed as part of this review.

## Conflicts of interest

The authors declare no competing interests.

## Acknowledgements

We are grateful for the financial support from the Science Fund for Distinguished Young Scholars of Tianjin Municipality (No. 23JCJQC00240), the National Natural Science Foundation of China (No. 52121002), the start-up grant of Peiyang Scholar program from Tianjin University, and the Fundamental Research Funds for the Central Universities, and the Opening Project of Hubei Longzhong Laboratory (2022KF-01). We also appreciate the Agency of Innovative Development of the Republic of Uzbekistan (Project FL-9024093524) for supporting this work.

## References

- W. Zhang, C. Sun, I. Angunawela, L. Meng, S. Qin, L. Zhou, S. Li, H. Zhuo, G. Yang, Z. G. Zhang, H. Ade and Y. Li, *Adv. Mater.*, 2022, **34**, e2108749.
- Y. Cui, Y. Xu, H. Yao, P. Bi, L. Hong, J. Zhang, Y. Zu, T. Zhang, J. Qin, J. Ren, Z. Chen, C. He, X. Hao, Z. Wei and J. Hou, *Adv. Mater.*, 2021, **33**, e2102420.
- M. F. Li, K. H. Xian, W. C. Zhao, D. Sheng, C. H. Liu, X. Li, W. W. Li and L. Ye, *Chem. Eng. J.*, 2023, **476**, 146723.
- M. Amjadi, Y. J. Yoon and I. Park, *Nanotechnology*, 2015, **26**, 375501.
- S. Li, J. Liu, V. Kuvondikov, J. Yan and L. Ye, *Matter*, 2025, **8**, 102062.
- J. S. Park, G. U. Kim, S. Lee, J. W. Lee, S. Li, J. Y. Lee and B. J. Kim, *Adv. Mater.*, 2022, **34**, e2201623.
- D. Koo, S. Jung, J. Seo, G. Jeong, Y. Choi, J. Lee, S. M. Lee, Y. Cho, M. Jeong, J. Lee, J. Oh, C. Yang and H. Park, *Joule*, 2020, **4**, 1021–1034.
- C. Xie, Y. Liu, W. Wei and Y. Zhou, *Adv. Funct. Mater.*, 2022, **33**, 2210675.
- K. Chong, X. Xu, H. Meng, J. Xue, L. Yu, W. Ma and Q. Peng, *Adv. Mater.*, 2022, **34**, e2109516.
- K. Xian, K. Zhou, M. Li, J. Liu, Y. Zhang, T. Zhang, Y. Cui, W. Zhao, C. Yang, J. Hou, Y. Geng and L. Ye, *Chin. J. Chem.*, 2023, **41**, 159–166.
- K. K. Zhou, K. H. Xian, Q. C. Qi, M. Y. Gao, Z. X. Peng, J. W. Liu, Y. Liu, S. M. Li, Y. D. Zhang, Y. H. Geng and L. Ye, *Adv. Funct. Mater.*, 2022, **32**, 2201781.
- J. W. Lee, C. Sun, B. S. Ma, H. J. Kim, C. Wang, J. M. Ryu, C. Lim, T. S. Kim, Y. H. Kim, S. K. Kwon and B. J. Kim, *Adv. Energy Mater.*, 2020, **11**, 2003367.
- Q. P. Fan, W. Y. Su, S. S. Chen, W. Kim, X. B. Chen, B. Lee, T. Liu, U. A. Méndez-Romero, R. J. Ma, T. Yang, W. L. Zhuang, Y. Li, Y. W. Li, T. S. Kim, L. T. Hou, C. Yang, H. Yan, D. H. Yu and E. G. Wang, *Joule*, 2020, **4**, 658–672.
- T. Kim, J. H. Kim, T. E. Kang, C. Lee, H. Kang, M. Shin, C. Wang, B. Ma, U. Jeong, T. S. Kim and B. J. Kim, *Nat. Commun.*, 2015, **6**, 8547.
- T. P. Brody, *IEEE Trans. Electron Devices*, 1984, **31**, 1614–1628.
- F. Garnier, R. Hajlaoui, A. Yassar and P. Srivastava, *Science*, 1994, **265**, 1684–1686.
- D. J. Lipomi, B. C. Tee, M. Vosgueritchian and Z. Bao, *Adv. Mater.*, 2011, **23**, 1771–1775.
- M. Kaltenbrunner, M. S. White, E. D. Glowacki, T. Sekitani, T. Someya, N. S. Sariciftci and S. Bauer, *Nat. Commun.*, 2012, **3**, 770.
- Z. Yang, J. Deng, X. Sun, H. Li and H. Peng, *Adv. Mater.*, 2014, **26**(2643–2647), 2613.
- Y. Ding, M. A. Invernale and G. A. Sotzing, *ACS Appl. Mater. Interfaces*, 2010, **2**, 1588–1593.
- J. A. Fan, W. H. Yeo, Y. Su, Y. Hattori, W. Lee, S. Y. Jung, Y. Zhang, Z. Liu, H. Cheng, L. Falgout, M. Bajema, T. Coleman, D. Gregoire, R. J. Larsen, Y. Huang and J. A. Rogers, *Nat. Commun.*, 2014, **5**, 3266.
- E. Dauzon, X. Sallenave, C. Plesse, F. Goubard, A. Amassian and T. D. Anthopoulos, *Adv. Mater.*, 2021, **33**, e2101469.
- D. J. Lipomi, H. Chong, M. Vosgueritchian, J. G. Mei and Z. A. Bao, *Sol. Energy Mater. Sol. Cells*, 2012, **107**, 355–365.
- S. Chen, S. Jung, H. J. Cho, N. H. Kim, S. Jung, J. Xu, J. Oh, Y. Cho, H. Kim, B. Lee, Y. An, C. Zhang, M. Xiao, H. Ki, Z. G. Zhang, J. Y. Kim, Y. Li, H. Park and C. Yang, *Angew. Chem., Int. Ed.*, 2018, **57**, 13277–13282.
- Z. Peng, K. Xian, Y. Cui, Q. Qi, J. Liu, Y. Xu, Y. Chai, C. Yang, J. Hou, Y. Geng and L. Ye, *Adv. Mater.*, 2021, **33**, 2106732.
- Y. T. Hsieh, J. Y. Chen, S. Fukuta, P. C. Lin, T. Higashihara, C. C. Chueh and W. C. Chen, *ACS Appl. Mater. Interfaces*, 2018, **10**, 21712–21720.

- 27 X. Wu, X. Zheng, T. Chen, S. Zhang, Y. Zhou, M. Wang, T. Chen, Y. Wang, Z. Bi, W. Fu, M. Du, W. Ma, L. Zuo and H. Chen, *Adv. Mater.*, 2024, **36**, e2406879.
- 28 K. K. Zhou, D. X. Han, K. H. Xian, S. M. Li, M. Y. Gao, K. Zhang, B. Zhao, X. Li, Y. Chen, Y. H. Geng and L. Ye, *Energy Environ. Sci.*, 2024, **17**, 5950–5961.
- 29 F. P. V. Koch, J. Rivnay, S. Foster, C. Müller, J. M. Downing, E. Buchaca-Domingo, P. Westacott, L. Y. Yu, M. J. Yuan, M. Baklar, Z. P. Fei, C. Luscombe, M. A. McLachlan, M. Heeney, G. Rumbles, C. Silva, A. Salleo, J. Nelson, P. Smith and N. Stingelin, *Prog. Polym. Sci.*, 2013, **38**, 1978–1989.
- 30 H. Kang, M. A. Uddin, C. Lee, K. H. Kim, T. L. Nguyen, W. Lee, Y. Li, C. Wang, H. Y. Woo and B. J. Kim, *J. Am. Chem. Soc.*, 2015, **137**, 2359–2365.
- 31 S. E. Root, S. Savagatrup, A. D. Printz, D. Rodriguez and D. J. Lipomi, *Chem. Rev.*, 2017, **117**, 6467–6499.
- 32 M. C. Xu, D. Zhang, Z. Y. Wang, Z. T. Liu, X. Gao, J. Y. He, Y. R. Gao, Z. L. Li and M. Shao, *Chem. Eng. J.*, 2022, **440**, 2201589.
- 33 J. W. Lee, T. N. L. Phan, E. S. Oh, H. G. Lee, T. S. Kim and B. J. Kim, *Adv. Funct. Mater.*, 2023, **33**, 2305851.
- 34 J. W. Lee, C. Sun, J. Lee, D. J. Kim, W. J. Kang, S. Lee, D. Kim, J. Park, T. N. L. Phan, Z. Tan, F. S. Kim, J. Y. Lee, X. Bao, T. S. Kim, Y. H. Kim and B. J. Kim, *Adv. Energy Mater.*, 2024, **14**, 2303872.
- 35 W. Liu, J. Yuan, C. Zhu, Q. Wei, S. Liang, H. Zhang, G. Zheng, Y. Hu, L. Meng, F. Gao, Y. Li and Y. Zou, *Sci. China: Chem.*, 2022, **65**, 1374–1382.
- 36 J. W. Lee, C. Sun, C. Lee, Z. P. Tan, T. N. L. Phan, H. Jeon, D. Jeong, S. K. Kwon, Y. H. Kim and B. J. Kim, *ACS Energy Lett.*, 2023, **8**, 1344–1353.
- 37 H. Yin, G. Xie, T. Wu, S. Liu, D. Chen and Y. Chen, *Macromol. Rapid Commun.*, 2024, e2400433.
- 38 Y. Ding, W. A. Memon, D. Zhang, Y. Zhu, S. Xiong, Z. Wang, J. Liu, H. Li, H. Lai, M. Shao and F. He, *Angew. Chem., Int. Ed.*, 2024, **63**, e202403139.
- 39 H. B. Chen, Z. Zhang, P. R. Wang, Y. X. Zhang, K. Q. Ma, Y. Lin, T. A. Duan, T. F. He, Z. F. Ma, G. K. Long, C. X. Li, B. Kan, Z. Y. Yao, X. J. Wan and Y. S. Chen, *Energy Environ. Sci.*, 2023, **16**, 1773–1782.
- 40 J. W. Lee, C. Sun, S. Lee, D. J. Kim, E. S. Oh, T. N. L. Phan, T. H. Q. Nguyen, S. Seo, Z. Tan, M. J. Lee, J. Y. Lee, X. C. Bao, T. S. Kim, C. Lee, Y. H. Kim and B. J. Kim, *Nano Energy*, 2024, **125**, 109541.
- 41 J. Liu, W. Zhou, J. Deng, X. Geng, S. Y. Jeong, Y. Cui, H. Y. Woo, F. Wu, F. Liu and L. Chen, *Nano Energy*, 2024, **121**, 109218.
- 42 Z. Zhang, S. Yuan, T. Chen, J. Wang, Y.-Q.-Q. Yi, B. Zhao, M. Li, Z. Yao, C. Li, X. Wan, G. Long, B. Kan and Y. Chen, *Energy Environ. Sci.*, 2024, **17**, 5719–5729.
- 43 W. Song, Q. Ye, S. Yang, L. Xie, Y. Meng, Z. Chen, Q. Gu, D. Yang, J. Shi and Z. Ge, *Angew. Chem., Int. Ed.*, 2023, **62**, e202310034.
- 44 F. Qi, Y. Li, R. Zhang, F. R. Lin, K. Liu, Q. Fan and A. K. Jen, *Angew. Chem., Int. Ed.*, 2023, **62**, e202303066.
- 45 S. You, Y. Zhang, B. Huang, S. Y. Jeong, X. Shuai, S. Huang, H. Y. Woo, F. Wu and L. Chen, *Adv. Funct. Mater.*, 2024, **35**, 2414803.
- 46 Q. Ye, Z. Chen, D. Yang, W. Song, J. Zhu, S. Yang, J. Ge, F. Chen and Z. Ge, *Adv. Mater.*, 2023, **35**, e2305562.
- 47 J. W. Lee, T. H. Q. Nguyen, W. J. Kang, S. Seo, S. Lee, S. Lee, J. Choi, J. Park, J. Y. Lee, T. S. Kim and B. J. Kim, *Energy Environ. Sci.*, 2025, **18**, 3325–3340.
- 48 J. W. Lee, C. Sun, S. W. Lee, G. U. Kim, S. Li, C. Wang, T. S. Kim, Y. H. Kim and B. J. Kim, *Energy Environ. Sci.*, 2022, **15**, 4672–4685.
- 49 J. W. Lee, S. W. Lee, J. Kim, Y. H. Ha, C. Sun, T. N. L. Phan, S. Lee, C. Wang, T. S. Kim, Y. H. Kim and B. J. Kim, *J. Mater. Chem. A*, 2022, **10**, 20312–20322.
- 50 H. P. Hu, W. Zhou, J. B. Liu, J. P. Xie, S. Y. You, S. Y. Jeong, H. Y. Woo, F. Y. Wu and L. Chen, *Chem. Eng. J.*, 2024, **491**, 152009.
- 51 Y. Ding, S. Xiong, W. A. Memon, D. Zhang, Z. Wang, M. Li, Z. Deng, H. Li, M. Shao and F. He, *Angew. Chem., Int. Ed.*, 2025, e202421430.
- 52 X. N. Luo, G. Freychet, Z. Q. Gan, K. An, H. J. Du, C. Wang, N. Li, W. K. Zhong and L. Ying, *Macromolecules*, 2023, **56**, 8928–8938.
- 53 J. Liu, J. Deng, Y. Zhu, X. Geng, L. Zhang, S. Y. Jeong, D. Zhou, H. Y. Woo, D. Chen, F. Wu and L. Chen, *Adv. Mater.*, 2023, **35**, e2208008.
- 54 J.-W. Lee, E. S. Oh, S. Lee, T. N.-L. Phan, T.-S. Kim, J.-Y. Lee, J. R. Reynolds and B. J. Kim, *Joule*, 2025, **9**, 101792.
- 55 J. Kim, G. U. Kim, D. J. Kim, S. Lee, D. Jeong, S. Seo, S. J. Ko, S. C. Yoon, T. S. Kim and B. J. Kim, *J. Mater. Chem. A*, 2023, **11**, 4808–4817.
- 56 J. W. Lee, H. G. Lee, E. S. Oh, S. W. Lee, T. N. Phan, S. Li, T. S. Kim and B. J. Kim, *Joule*, 2024, **8**, 204–223.
- 57 C. Lin, R. Peng, W. Song, J. Gao, T. Feng, Y. Bai, Q. Liu, M. Yang, J. Zhang and Z. Ge, *Angew. Chem., Int. Ed.*, 2025, **64**, e202420121.
- 58 H. G. Lee, J. W. Lee, E. S. Oh, M. J. Lee, T. S. Kim, C. Lee and B. J. Kim, *J. Mater. Chem. A*, 2024, **12**, 19039–19051.
- 59 J. W. Lee, S. Seo, S. W. Lee, G. U. Kim, S. Han, T. N. Phan, S. Lee, S. Li, T. S. Kim, J. Y. Lee and B. J. Kim, *Adv. Mater.*, 2022, **34**, e2207544.
- 60 Q. P. Wan, H. Jeon, S. Seo, E. S. Oh, J. W. Lee, C. Wang, T. S. Kim, B. J. Kim and B. C. Thompson, *Chem. Mater.*, 2023, **35**, 10476–10486.
- 61 H. Ke, M. Gao, S. Li, Q. Qi, W. Zhao, X. Li, S. Li, V. Kuvondikov, P. Lv, Q. Wei and L. Ye, *Sol. RRL*, 2023, **7**, 2300109.
- 62 Q. Wan, S. Seo, S. W. Lee, J. Lee, H. Jeon, T. S. Kim, B. J. Kim and B. C. Thompson, *J. Am. Chem. Soc.*, 2023, **145**, 11914–11920.
- 63 H. Wang, H. Kou, J. Pan, X. Wang, D. Liu and R. Yang, *Small*, 2025, e2412767.
- 64 J. G. Mei and Z. N. Bao, *Chem. Mater.*, 2014, **26**, 604–615.
- 65 D. Rodriguez, J. G. Kohl, P. Morel, K. Burrows, G. Favaro, S. E. Root, J. Ramirez, M. A. Alkhadra, C. W. Carpenter,

- Z. Fei, P. Boufflet, M. Heeney and D. J. Lipomi, *ACS Macro Lett.*, 2018, **7**, 1003–1009.
- 66 X. Li, H. Z. Ke, S. S. Li, M. Y. Gao, S. M. Li, J. F. Yu, H. J. Xie, K. K. Zhou, K. Zhang and L. Ye, *Adv. Funct. Mater.*, 2024, **34**, 2400702.
- 67 J. He, D. Zhang, J. Liu, L. Yang, Y. Gao and M. Shao, *ACS Appl. Mater. Interfaces*, 2024, **16**, 22294–22302.
- 68 Z. Wang, D. Zhang, L. Yang, O. Allam, Y. Gao, Y. Su, M. Xu, S. Mo, Q. Wu, Z. Wang, J. Liu, J. He, R. Li, X. Jia, Z. Li, L. Yang, M. D. Weber, Y. Yu, X. Zhang, T. J. Marks, N. Stingelin, J. Kacher, S. S. Jang, A. Facchetti and M. Shao, *Science*, 2025, **387**, 381–387.
- 69 D. Zhang, J. F. Liu, X. Gao, Z. Wang, J. Y. He, Z. Y. Wang, L. Yang, Y. R. Gao and M. Shao, *Energy Environ. Sci.*, 2025, **18**, 2342–2352.
- 70 S. Savagatrup, A. D. Printz, D. Rodriguez and D. J. Lipomi, *Macromolecules*, 2014, **47**, 1981–1992.
- 71 L. Ma, Y. Cui, J. Zhang, K. Xian, Z. Chen, K. Zhou, T. Zhang, W. Wang, H. Yao, S. Zhang, X. Hao, L. Ye and J. Hou, *Adv. Mater.*, 2023, **35**, e2208926.
- 72 M. F. Li, Z. X. Peng, K. H. Xian, W. C. Zhao, C. X. Liu, Y. Chen, C. H. Cui and L. Ye, *J. Mater. Chem. A*, 2023, **11**, 5606–5614.
- 73 T. Liu, K. Zhou, R. Ma, L. Zhang, C. Huang, Z. Luo, H. Zhu, S. Yao, C. Yang, B. Zou and L. Ye, *Aggregate*, 2023, **4**, e308.
- 74 G. U. Kim, C. Choi, D. Jeong, D. J. Kim, T. N. L. Phan, S. Song, J. Park, T. S. Kim, Y. H. Kim and B. J. Kim, *Adv. Energy Mater.*, 2023, **13**, 2302125.
- 75 Z. Y. Wang, D. Zhang, L. Yang, M. C. Xu, J. F. Liu, Z. Wang, Y. R. Gao, L. Y. Zhang, L. B. Niu and M. Shao, *ACS Mater. Lett.*, 2024, **6**, 4710–4718.
- 76 K. H. Xian, K. Zhang, T. Zhang, K. K. Zhou, Z. G. Zhang, J. H. Hou, H. L. Zhang, Y. H. Geng and L. Ye, *Energy Environ. Sci.*, 2025, **18**, 2570–2583.
- 77 W. Song, K. Yu, J. Ge, L. Xie, R. Zhou, R. Peng, X. Zhang, M. Yang, Z. Wei and Z. Ge, *Matter*, 2022, **5**, 1877–1889.
- 78 Z. Peng, K. Xian, J. Liu, Y. Zhang, X. Sun, W. Zhao, Y. Deng, X. Li, C. Yang, F. Bian, Y. Geng and L. Ye, *Adv. Mater.*, 2023, **35**, 2207884.
- 79 Y. Bai, S. Li, Q. Wang, Q. Chen, Z. Zhang, S. Meng, Y. Zang, H. Fu, L. Xue, L. Ye and Z. Zhang, *Natl. Sci. Rev.*, 2025, **12**, nwaf019.
- 80 N. Balar, J. J. Rech, R. Henry, L. Ye, H. Ade, W. You and B. T. O'Connor, *Chem. Mater.*, 2019, **31**, 5124–5132.
- 81 A. A. Shafe, H. M. Schrickx, K. Ding, H. Ade and B. T. O'Connor, *ACS Energy Lett.*, 2023, **8**, 3720–3726.
- 82 S. A. Mollinger, B. A. Krajina, R. Noriega, A. Salleo and A. J. Spakowitz, *ACS Macro Lett.*, 2015, **4**, 708–712.
- 83 S. Li, M. Gao, K. Zhou, X. Li, K. Xian, W. Zhao, Y. Chen, C. He and L. Ye, *Adv. Mater.*, 2024, **36**, 2307278.
- 84 J. W. Lee, T. H. Q. Nguyen, E. S. Oh, S. Lee, J. Choi, H. S. Kwon, C. Wang, S. Lee, J. Y. Lee, T. S. Kim and B. J. Kim, *Adv. Energy Mater.*, 2024, **14**, 2401191.
- 85 W. B. Tang, Z. C. Ding, Y. L. Su, Q. Weng, Y. Zhang, R. P. Li, W. L. Huang, Z. C. Wang, Y. Wu, Y. C. Han, K. Zhao, Z. Yang, X. C. Wang and S. Z. Liu, *Adv. Funct. Mater.*, 2024, **34**, 2312289.
- 86 C. Y. Zhang, Y. Q. Liu, H. X. Li, X. Y. Cui, Z. D. Wei, Y. H. Liu, M. H. Li, A. D. Zhang, P. Cheng and Z. S. Bo, *Chin. J. Polym. Sci.*, 2025, **43**, 271–277.
- 87 X. Zheng, X. Wu, Q. Wu, Y. Han, G. Ding, Y. Wang, Y. Kong, T. Chen, M. Wang, Y. Zhang, J. Xue, W. Fu, Q. Luo, C. Ma, W. Ma, L. Zuo, M. Shi and H. Chen, *Adv. Mater.*, 2024, **36**, e2307280.
- 88 W. Y. Yang, X. N. Luo, M. K. Li, C. Q. Shi, Z. Y. Wang, Z. Y. Yang, J. M. Wu, X. W. Zhang, W. B. Huang, D. G. Ma, C. Wang, W. K. Zhong and L. Ying, *Adv. Energy Mater.*, 2024, **15**, 2403259.
- 89 H. Li, J. Le, H. Tan, L. Hu, X. Li, K. Zhang, S. Zeng, Q. Liu, M. Zhang, L. Shi, Z. Cai, S. Liu, H. Li, L. Ye, X. Hu and Y. Chen, *Adv. Mater.*, 2025, **37**, e2411989.
- 90 X. Kang, Y. Bao, T. Y. Feng, Y. W. Wu, Y. W. Zhang, Y. Zhao, C. M. Yang, M. L. Sun and X. C. Bao, *Chem. Eng. J.*, 2023, **476**, 146828.
- 91 J. Zhang, Q. Chen, M. Li, G. Zhang, Z. Zhang, X. Deng, J. Xue, C. Zhao, C. Xiao, W. Ma and W. Li, *Adv. Mater.*, 2024, **36**, e2312805.
- 92 Z. C. Ding, Y. Zhang, Y. L. Su, Y. Wu, Y. C. Han, K. Zhao and S. Z. Liu, *Energy Environ. Mater.*, 2023, **6**, e12421.
- 93 Z. Wang, D. Zhang, M. Xu, J. Liu, J. He, L. Yang, Z. Li, Y. Gao and M. Shao, *Small*, 2022, **18**, e2201589.
- 94 Y. C. Tseng, Q. P. Fan, C. Y. Tsai, J. F. Chang, M. H. Yu, H. Z. Tseng, H. L. Yip, F. R. Lin, A. K. Y. Jen and C. C. Chueh, *Adv. Funct. Mater.*, 2024, **34**, 2408993.
- 95 M. S. Wang, K. Zheng and X. M. Cai, *Opt. Mater.*, 2025, **159**, 116639.
- 96 M. Y. Aliouat, S. Escoubas, M. C. Benoudia, D. Ksenzov, D. Duché, E. Bènevent, C. Vidélot-Ackermann, J. Ackermann, O. Thomas and S. Grigorian, *J. Appl. Phys.*, 2020, **127**, 045108.
- 97 Y. Chen, S. M. Li, Z. B. Shen, C. L. Sun, J. T. Feng and L. Ye, *Sci. China Mater.*, 2024, **67**, 3917–3924.
- 98 Y. Bae, D. Kim, S. Li, Y. Choi, S. Son, T. Park and L. Ye, *Prog. Polym. Sci.*, 2024, **159**, 101899.
- 99 Z. Peng, K. Xian, J. Liu, Y. Zhang, X. Sun, W. Zhao, Y. Deng, X. Li, C. Yang, F. Bian, Y. Geng and L. Ye, *Adv. Mater.*, 2023, **35**, 2207884.
- 100 K. Xian, R. Ma, K. Zhou, J. Liu, M. Gao, W. Zhao, M. Li, Y. Geng and L. Ye, *Aggregate*, 2024, **5**, e466.
- 101 L. Pei, D. Han, Y. Wang, M. Gao, J. Wu, C. Sun, M. Yu, Y. Wang, X. Li, H. Ke and L. Ye, *Adv. Funct. Mater.*, 2025, DOI: [10.1002/adfm.202425892](https://doi.org/10.1002/adfm.202425892).
- 102 K. Zhou, W. Zhai, V. Kuvondikov, K. Dai and L. Ye, *Nexus*, 2025, DOI: [10.1016/j.nexus.2025.100072](https://doi.org/10.1016/j.nexus.2025.100072).
- 103 R. Ma, Z. Luo, Y. Zhang, L. Zhan, T. Jia, P. Cheng, C. Yan, Q. Fan, S. Liu, L. Ye, G. Zhang, X. Xu, W. Gao, Y. Wu, J. Wu, Y. Li, Y. Liu, F. Liu, J. Song, H. Chen, W. Chen, X. Zhang, Y. Liu, J. Yuan, Q. Liu, Z. Kan, H. Yin, X. Li, Y. Ma, D. Deng, L. Zhu, Y. Huo, B. Fan, H. Fu, X. Liao, H. Hu, C. Li, R. Yu, H. Hu, Z. Yao, Y. Cai, D. Qian, Y. Cui, H. Yao, B. Xu, B. Kan, K. Gao, C. Duan, X. Hu and H. Sun, *Sci. China Mater.*, 2025, DOI: [10.1007/s40843-025-3366-9](https://doi.org/10.1007/s40843-025-3366-9).